Agilent
E4991A RF Impedance/Material Analyzer

Data Sheet

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Definitions

All specifications apply over a 5 °C to 40 °C range (unless otherwise stated) and 30 minutes after the instrument has been turned on.

Specification (spec.)
Warranted performance. Specifications include guardbands to account for the expected statistical performance distribution, measurement uncertainties, and changes in performance due to environmental conditions.

Supplemental information is intended to provide information useful in applying the instrument, but that is not covered by the product warranty. The information is denoted as typical, or nominal.

Typical (typ.)
Expected performance of an average unit which does not include guardbands. It is not covered by the product warranty.

Nominal (nom.)
A general, descriptive term that does not imply a level of performance. It is not covered by the product warranty.

Measurement Parameters and Range

Measurement parameters

Impedance parameters:
$|Z|$, $|Y|$, L_s, L_p, C_s, C_p, $R_s(R)$, R_p, X, G, B, D, Q, θ_z, θ_y, $|\Gamma|$, Γ_x, Γ_y, θ_γ

Material parameters (option E4991A-002):
(see *"Option E4991A-002 material measurement (typical)"* on page 17)
Permittivity parameters: $|\varepsilon_r|$, ε_r', ε_r'', tanδ
Permeability parameters: $|\mu_r|$, μ_r', μ_r'', tanδ

Measurement range

Measurement range (|Z|):
130 mΩ to 20 kΩ.
(Frequency= 1 MHz,
Point averaging factor ≥ 8,
Oscillator level= –3 dBm; = –13 dBm; or = –23 dBm,
Measurement accuracy ≤ ±10%,
Calibration is performed within 23 °C ±5 °C,
Measurement is performed within ±5 °C of calibration temperature)

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Source Characteristics

Frequency

Range:
1 MHz to 3 GHz

Resolution:
1 mHz

Accuracy:
without Option E4991A-1D5:
±10 ppm (23 °C ±5 °C)
±20 ppm (5 °C to 40 °C)
with Option E4991A-1D5:
±1 ppm (5 °C to 40 °C)

Stability:
with Option E4991A-1D5:
±0.5 ppm/year (5 °C to 40 °C)

Oscillator level

Range:
Power (when 50 Ω load is connected to test port):
–40 dBm to 1 dBm (frequency ≤ 1 GHz)
–40 dBm to 0 dBm (frequency > 1 GHz[1])
Current (when short is connected to test port):
0.0894 mArms to 10 mArms (frequency ≤ 1 GHz)
0.0894 mArms to 8.94 mArms (frequency > 1 GHz[1])
Voltage (when open is connected to test port):
4.47 mVrms to 502 mVrms (frequency ≤ 1 GHz)
4.47 mVrms to 447 mVrms (frequency > 1 GHz[1])

Resolution:
0.1 dB[2]

Accuracy:
(Power, when 50 Ω load is connected to test port)
Frequency ≤ 1 GHz:
±2 dB (23 °C ±5 °C)
±4 dB (5 °C to 40 °C)
Frequency > 1 GHz:
±3 dB (23 °C ±5 °C)
±5 dB (5 °C to 40 °C)
with Option E4991A-010:
Frequency ≤ 1 GHz
±3.5 dB (23 °C ± 5 °C)
±5.5 dB (5 °C to 40 °C)
Frequency > 1 GHz
±5.6 dB (23 °C ± 5 °C)
±7.6 dB (5 °C to 40 °C)

Output impedance

Output impedance:
50 Ω (nominal)

DC Bias (Option E4991A-001)

DC voltage bias

Range:
0 to ±40 V

Resolution:
1 mV

Accuracy:
±{0.1% + 6 mV + (Idc[mA] x 20 Ω)[mV]}
(23 °C ±5 °C)
±{0.2% + 12 mV + (Idc[mA] x 40 Ω)[mV]}
(5 °C to 40 °C)

DC current bias

Range:
100 µA to 50 mA, –100 µA to –50 mA

Resolution:
10 µA

Accuracy:
±{0.2% + 20 µA + (Vdc[V]/10 kΩ)[mA]}
(23 °C ±5 °C)
±{0.4% + 40 µA + (Vdc[V]/5 kΩ)[mA]}
(5 °C to 40 °C)

DC bias monitor

Monitor parameters:
Voltage and current

Voltage monitor accuracy:
±{0.5% + 15 mV + (Idc[mA] x 2 Ω)[mV]}
(23 °C ±5 °C, typical)
±{1.0% + 30 mV + (Idc[mA] x 4 Ω)[mV]}
(5 °C to 40 °C, typical)

Current monitor accuracy:
±{0.5% + 30 µA + (Vdc[V] / 40 k Ω)[mA]}
(23 °C ±5 °C, typical)
±{1.0% + 60 µA + (Vdc[V] / 20 k Ω)[mA]}
(5 °C to 40 °C, typical)

1. It is possible to set more than 0 dBm (447 mV, 8.94 mA) oscillator level at frequency > 1 GHz. However, the characteristics at this setting are not guaranteed.
2. When the unit is set at mV or mA, the entered value is rounded to 0.1 dB resolution.

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Probe Station Connection Kit (Option E4991A-010)

Oscillator level

Power accuracy:
Frequency ≤ 1 GHz:
±5.5 dB (5 °C to 40 °C)
Frequency > 1 GHz:
±7.6 dB (5 °C to 40 °C)

Sweep Characteristics

Sweep conditions

Sweep parameters:
Frequency, oscillator level (power, voltage, current), DC bias voltage, DC bias current

Sweep range setup:
Start/stop or center/span

Sweep types:
Frequency sweep: linear, log, segment
Other parameters sweep: linear, log

Sweep mode:
Continuous, single

Sweep directions:
Oscillator level, DC bias (voltage and current): up sweep, down sweep
Other parameters sweep: up sweep

Number of measurement points:
2 to 801

Delay time:
Types: point delay, sweep delay, segment delay
Range: 0 to 30 sec
Resolution: 1 msec

Segment sweep

Available setup parameters for each segment:
Sweep frequency range, number of measurement points, point averaging factor, oscillator level (power, voltage, or current), DC bias (voltage or current), DC bias limit (current limit for voltage bias, voltage limit for current bias)

Number of segments:
1 to 16

Sweep span types:
Frequency base or order base

Measurement Accuracy

Conditions for defining accuracy

Temperature:
23 °C ±5 °C

Accuracy-specified plane:
7-mm connector of test head

Accuracy defined measurement points:
Same points at which the calibration is done.

Accuracy when open/short/load calibration is performed

|Z|, |Y|: $\pm(E_a + E_b)$ [%]
(see Figures 1 through 4 for examples of calculated accuracy)

θ: $\pm \dfrac{(E_a + E_b)}{100}$ [rad]

L, C, X, B: $\pm (E_a + E_b) \times \sqrt{(1 + D_x^2)}$ [%]

R, G: $\pm (E_a + E_b) \times \sqrt{(1 + Q_x^2)}$ [%]

D:

at $\left|D_x \tan\left(\dfrac{E_a + E_b}{100}\right)\right| < 1$ $\pm \dfrac{(1 + D_x^2)\tan\left(\dfrac{E_a + E_b}{100}\right)}{1 \mp D_x \tan\left(\dfrac{E_a + E_b}{100}\right)}$

at $D_x \leq 0.1$ $\pm \dfrac{E_a + E_b}{100}$

Q:

at $\left|Q_x \tan\left(\dfrac{E_a + E_b}{100}\right)\right| < 1$ $\pm \dfrac{(1 + Q_x^2)\tan\left(\dfrac{E_a + E_b}{100}\right)}{1 \mp Q_x \tan\left(\dfrac{E_a + E_b}{100}\right)}$

at $\dfrac{10}{E_a + E_b} \geq Q_x \geq 10$ $\pm Q_x^2 \dfrac{E_a + E_b}{100}$

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Accuracy when open/short/load/low-loss capacitor calibration is performed

|Z|, |Y|: $\pm(E_a + E_b)$ [%]

θ: $\pm \dfrac{E_c}{100}$ [rad]

L, C, X, B: $\pm \sqrt{(E_a + E_b)^2 + (E_c D_x)^2}$ [%]

R, G: $\pm \sqrt{(E_a + E_b)^2 + (E_c Q_x)^2}$ [%]

D:

at $\left|D_x \tan\left(\dfrac{E_c}{100}\right)\right| < 1 \pm \dfrac{(1 + D_x^2)\tan\left(\dfrac{E_c}{100}\right)}{1 \mp D_x \tan\left(\dfrac{E_c}{100}\right)}$

at $D_x \leq 0.1$ $\pm \dfrac{E_c}{100}$

Q:

at $\left|Q_x \tan\left(\dfrac{E_c}{100}\right)\right| < 1 \pm \dfrac{(1 + Q_x^2)\tan\left(\dfrac{E_c}{100}\right)}{1 \mp Q_x \tan\left(\dfrac{E_c}{100}\right)}$

at $\dfrac{10}{E_c} \geq Q_x \geq 10$ $\pm Q_x^2 \dfrac{E_c}{100}$

(See Figure 5)

Definition of each parameter

Dx = Measurement value of D

Qx = Measurement value of Q

Ea = (Within ±5 °C from the calibration temperature. Measurement accuracy applies when the calibration is performed at 23 °C ±5 °C. When the calibration is performed beyond 23 °C ±5 °C, measurement error doubles.)

at oscillator level ≥ –33 dBm:
- ±0.65 [%] (1 MHz ≤ Frequency ≤ 100 MHz)
- ±0.8 [%] (100 MHz < Frequency ≤ 500 MHz)
- ±1.2 [%] (500 MHz < Frequency ≤ 1 GHz)
- ±2.5 [%] (1 GHz < Frequency ≤ 1.8 GHz)
- ±5 [%] (1.8 GHz < Frequency ≤ 3 GHz)

at Oscillator level < –33 dBm:
- ±1 [%] (1 MHz ≤ Frequency ≤ 100 MHz)
- ±1.2 [%] (100 MHz < Frequency ≤ 500 MHz)
- ±1.2 [%] (500 MHz < Frequency ≤ 1 GHz)
- ±2.5 [%] (1 GHz < Frequency ≤ 1.8 GHz)
- ±5 [%] (1.8 GHz < Frequency ≤ 3 GHz)

Eb = $\pm \left(\dfrac{Z_s}{|Z_x|} + Y_o \bullet |Z_x|\right) \times 100$ [%]

(|Zx|: measurement value of |Z|)

Ec = $\pm \left(0.06 + \dfrac{0.08 \times F}{1000}\right)$ [%]

(F: frequency [MHz], typical)

Zs = (Within ±5 °C from the calibration temperature. Measurement accuracy applies when the calibration is performed at 23 °C ±5 °C. When the calibration is performed beyond 23 °C ±5 °C, the measurement accuracy decreases to half that described. F: frequency [MHz].)

at oscillator level = –3 dBm, –13 dBm, or –23 dBm:
- $\pm(13 + 0.5 \times F)$ [mΩ] (averaging factor ≥ 8)
- $\pm(25 + 0.5 \times F)$ [mΩ] (averaging factor ≤ 7)

at oscillator level ≥ –33 dBm
- $\pm(25 + 0.5 \times F)$ [mΩ] (averaging factor ≥ 8)
- $\pm(50 + 0.5 \times F)$ [mΩ] (averaging factor ≤ 7)

at oscillator level < –33 dBm
- $\pm(50 + 0.5 \times F)$ [mΩ] (averaging factor ≥ 8)
- $\pm(100 + 0.5 \times F)$ [mΩ] (averaging factor ≤ 7)

Yo = (Within ±5 °C from the calibration temperature. Measurement accuracy applies when the calibration is performed at 23 °C ±5 °C. When the calibration is performed beyond 23 °C ±5 °C, the measurement accuracy decreases to half that described. *F*: frequency [MHz].)

at oscillator level = –3 dBm, –13 dBm, –23 dBm:
- $\pm(5 + 0.1 \times F)$ [μ*S*] (averaging factor ≥ 8)
- $\pm(10 + 0.1 \times F)$ [μ*S*] (averaging factor ≤ 7)

at oscillator level ≥ –33 dBm:
- $\pm(10 + 0.1 \times F)$ [μ*S*] (averaging factor ≥ 8)
- $\pm(30 + 0.1 \times F)$ [μ*S*] (averaging factor ≤ 7)

at oscillator level < –33 dBm
- $\pm(20 + 0.1 \times F)$ [μ*S*] (averaging factor ≥ 8)
- $\pm(60 + 0.1 \times F)$ [μ*S*] (averaging factor ≤ 7)

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Measurement Accuracy
(continued)

Examples of calculated impedance measurement accuracy

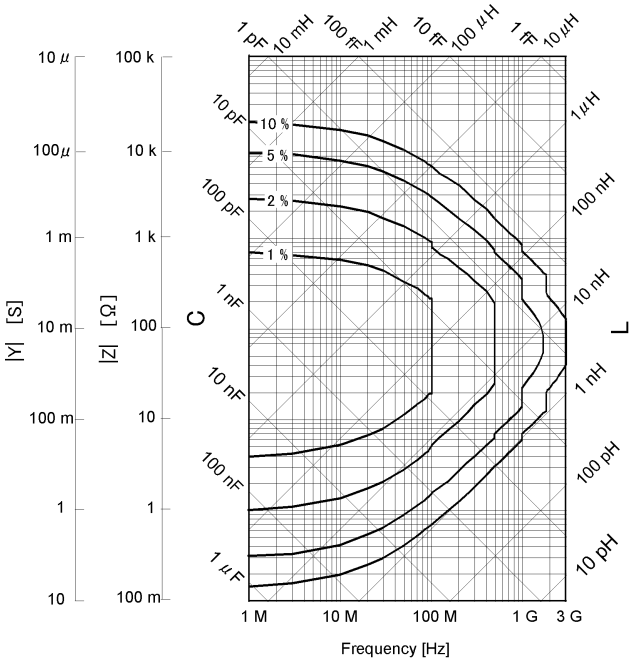

Figure 1. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level = –23 dBm, –13 dBm, –3 dBm. Point averaging factor ≥ 8 within ±5 °C from the calibration temperature.

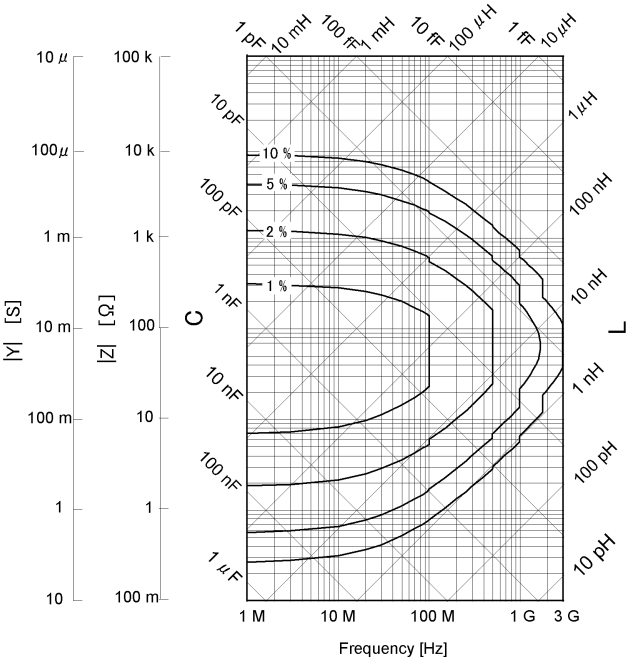

Figure 2. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level ≥ –33 dBm. Point averaging factor ≥ 8 within ±5 °C from the calibration temperature.

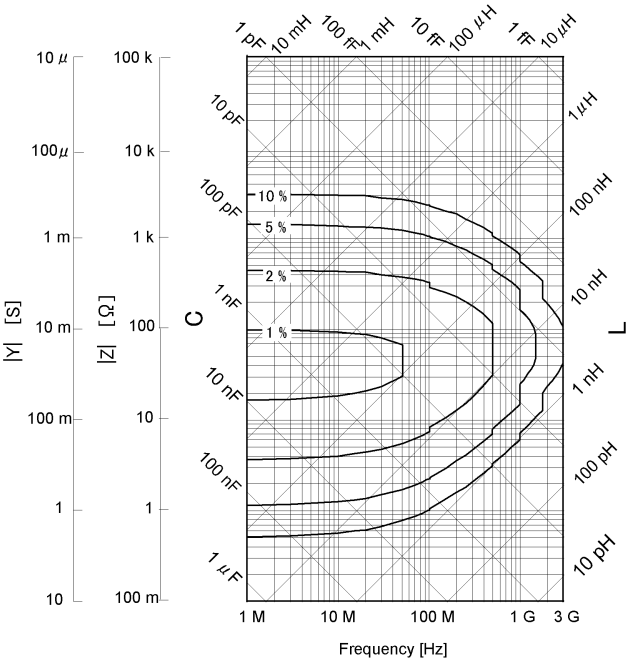

Figure 3. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level ≥ –33 dBm. Point averaging factor ≤ 7 within ±5 °C from the calibration temperature.

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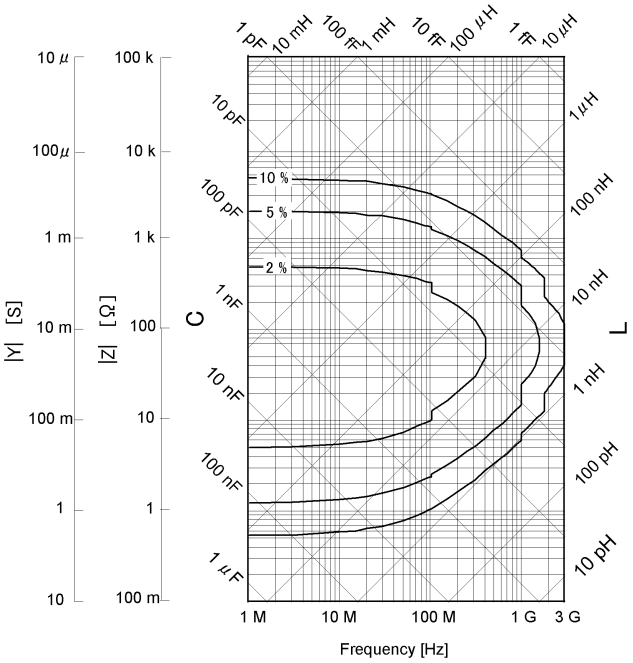

Figure 4. |Z|, |Y| Measurement accuracy when open/short/load calibration is performed. Oscillator level < –33 dBm within ±5 °C from the calibration temperature.

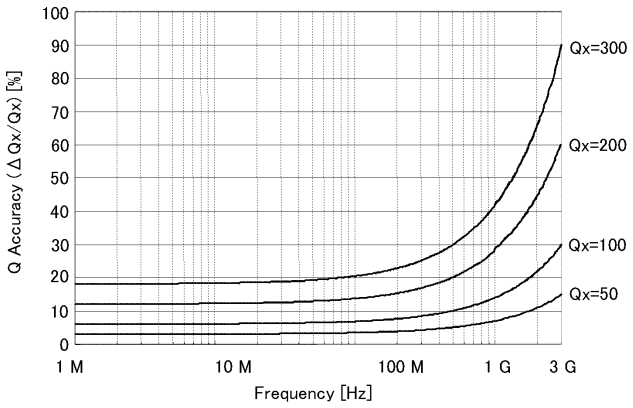

Figure 5. Q Measurement accuracy when open/short/load/low-loss capacitor calibration is performed (typical).

Measurement Support Functions

Error correction

Available calibration and compensation

Open/short/load calibration:

Connect open, short, and load standards to the desired reference plane and measure each kind of calibration data. The reference plane is called the calibration reference plane.

Low-loss capacitor calibration:

Connect the dedicated standard (low-loss capacitor) to the calibration reference plane and measure the calibration data.

Port extension compensation (fixture selection):

When a device is connected to a terminal that is extended from the calibration reference plane, set the electrical length between the calibration plane and the device contact. Select the model number of the registered test fixtures in the E4991A's setup toolbar or enter the electrical length for the user's test fixture.

Open/short compensation:

When a device is connected to a terminal that is extended from the calibration reference plane, make open and/or short states at the device contact and measure each kind of compensation data.

Calibration/compensation data measurement point

User-defined point mode:

Obtain calibration/compensation data at the same frequency and power points as used in actual device measurement, which are determined by the sweep setups. Each set of calibration/compensation data is applied to each measurement at the same point. If measurement points (frequency and/or power) are changed by altering the sweep setups, calibration/compensation data become invalid and calibration or compensation data acquisition is again required.

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Measurement Support Functions *(continued)*

Fixed frequency and fixed power point mode:
Obtain calibration/compensation data at fixed frequency and power points covering the entire frequency and power range of the E4991A. In device measurement, calibration or compensation is applied to each measurement point by using interpolation. Even if the measurement points (frequency and/or power) are changed by altering the sweep setups, you don't need to retake the calibration or compensation data.

Fixed frequency and user-defined power point mode:
Obtain calibration/compensation data at fixed frequency points covering the entire frequency range of the E4991A and at the same power points as used in actual device measurement which are determined by the sweep setups. Only if the power points are changed, calibration/compensation data become invalid and calibration or compensation data acquisition is again required.

Trigger

Trigger mode:
Internal, external (external trigger input connector), bus (GPIB), manual (front key)

Averaging

Types:
Sweep-to-sweep averaging, point averaging

Setting range:
Sweep-to-sweep averaging: 1 to 999 (integer)
Point averaging: 1 to 100 (integer)

Display

LCD display :
Type/size: color LCD, 8.4 inch (21.3 cm)
Resolution: 640 (horizontal) × 480 (vertical)

Number of traces:
Data trace: 3 scalar traces + 2 complex traces (maximum)
Memory trace: 3 scalar traces + 2 complex traces (maximum)

Trace data math:
Data – memory, data/memory (for complex parameters), delta% (for scalar parameters), offset

Format:
For scalar parameters: linear Y-axis, log Y-axis
For complex parameters: *Z*, *Y*: polar, complex; Γ: polar, complex, Smith, admittance

Other display functions:
Split/overlay display (for scalar parameters), phase expansion

Marker

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Number of markers:
Main marker: one for each trace (marker 1)
Sub marker: seven for each trace (marker 2 to marker 8)
Reference marker: one for each trace (marker R)

Marker search:
Search type: maximum, minimum, target, peak
Search track: performs search with each sweep

Other functions:
Marker continuous mode, marker coupled mode, marker list, marker statistics

Equivalent circuit analysis

Circuit models:
3-component model (4 models),
4-component model (1 model)

Analysis types:
Equivalent circuit parameters calculation, frequency characteristics simulation

Limit marker test

Number of markers for limit test:
9 (marker R, marker 1 to 8)

Setup parameters for each marker:
Stimulus value, upper limit, and lower limit

Mass storage

Built-in flexible disk drive:
3.5 inch, 720 KByte or 1.44 MByte, DOS format

Hard disk drive:
2 GByte (minimum)

Stored data:
State (binary), measurement data (binary, ASCII or CITI file), display graphics (bmp, jpg), VBA program (binary)

Interface

GPIB

Standard conformity:
IEEE 488.1-1987, IEEE 488.2-1987

Available functions (function code)[3]:
SH1, AH1, T6, TE0, L4, LE0, SR1, RL0, PP0, DT1, DC1, C0, E2

Numerical data transfer format:
ASCII

Protocol:
IEEE 488.2-1987

Printer parallel port

Interface standard:
IEEE 1284 Centronics

Connector type:
25-pin D-sub connector, female

LAN interface

Standard conformity:
10 Base-T or 100 Base-TX (automatically switched), Ethertwist, RJ45 connector

Protocol:
TCP/IP

Functions:
FTP

USB Port

Interface standard:
USB 1.1

Connector type:
Standard USB A, female

Available functions:
Provides connection to printers and USB/GPIB Interface.

3. Refer to the standard for the meaning of each function code.

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Measurement Terminal (At Test Head)

Connector type:
7-mm connector

Rear panel connectors

External reference signal input connector

Frequency:
10 MHz ±10 ppm (typical)

Level:
0 dBm to +6 dBm (typical)

Input impedance:
50 Ω (nominal)

Connector type:
BNC, female

Internal reference signal output connector

Frequency:
10 MHz (nominal)

Accuracy of frequency:
Same as frequency accuracy described in *"Frequency"* on page 3

Level:
+2 dBm (nominal)

Output impedance:
50 Ω (nominal)

Connector type:
BNC, female

High stability frequency reference output connector (Option E4991A-1D5)

Frequency:
10 MHz (nominal)

Accuracy of frequency:
Same as frequency accuracy described in *"Frequency"* on page 3

Level:
+2 dBm (nominal)

Output impedance:
50 Ω (nominal)

Connector type:
BNC, female

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External trigger input connector

Level:
LOW threshold voltage: 0.5 V
HIGH threshold voltage: 2.1 V
Input level range: 0 V to +5 V

Pulse width (Tp):
≥ 2 µsec (typical). See Figure 6 for definition of Tp.

Polarity:
Positive or negative (selective)

Connector type:
BNC, female

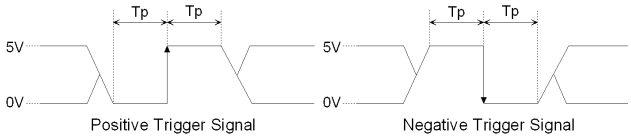

Figure 6. Definition of pulse width (Tp)

General Characteristics

Environment conditions

Operating condition

Temperature:
5 °C to 40 °C

Humidity:
(at wet bulb temperature ≤ 29 °C, without condensation)
Flexible disk drive non-operating condition:
15% to 90% RH
Flexible disk drive operating condition:
20% to 80% RH

Altitude:
0 m to 2,000 m (0 feet to 6,561 feet)

Vibration:
0.5 G maximum, 5 Hz to 500 Hz

Warm-up time:
30 minutes

Non-operating storage condition

Temperature:
–20 °C to +60 °C

Humidity:
(at wet bulb temperature ≤ 45 °C, without condensation)
15% to 90% RH

Altitude:
0 m to 4,572 m (0 feet to 15,000 feet)

Vibration:
1 G maximum, 5 Hz to 500 Hz

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General Characteristics
(continued)

Other specifications

EMC
European Council Directive 89/336/EEC

CE ISM 1-A

IEC 61326-1:1997+A1
  CISPR 11:1990 / EN 55011:1991 Group 1, Class A
IEC 61000-4-2:1995 / EN 61000-4-2:1995
  4 kV CD / 4 kV AD
IEC 61000-4-3:1995 / EN 61000-4-3:1996
  3 V/m, 80-1000 MHz, 80% AM
IEC 61000-4-4:1995 / EN 61000-4-4:1995
  1 kV power / 0.5 kV Signal
IEC 61000-4-5:1995 / EN 61000-4-5:1995
  0.5 kV Normal / 1 kV Common
IEC 61000-4-6:1996 / EN 61000-4-6:1996
  3 V, 0.15-80 MHz, 80% AM
IEC 61000-4-11:1994 / EN 61000-4-11:1994
  100% 1cycle

Note: When tested at 3 V/m according to EN 61000-4-3:1996, the measurement accuracy will be within specifications over the full immunity test frequency range of 80 MHz to 1000 MHz except when the analyzer frequency is identical to the transmitted interference signal test frequency.

N10149

AS/NZS 2064.1/2 Group 1, Class A

Safety

CE ISM 1-A

European Council Directive 73/23/EEC
IEC 61010-1:1990+A1+A2 / EN 61010-1:1993+A2
  INSTALLATION CATEGORY II, POLLUTION DEGREE 2
  INDOOR USE
IEC60825-1:1994 CLASS 1 LED PRODUCT

SP LR95111C

CAN/CSA C22.2 No. 1010.1-92

Power requirements

90 V to 132 V, or 198 V to 264 V (automatically switched), 47 Hz to 63 Hz, 350 VA maximum

Weight
Main unit: 17 kg (nominal)
Test head: 1 kg (nominal)

Dimensions
Main unit: See Figure 7 through Figure 9
Test head: See Figure 10
Option E4991A-007 test head dimensions: See Figure 11
Option E4991A-010 test head dimensions: See Figure 12

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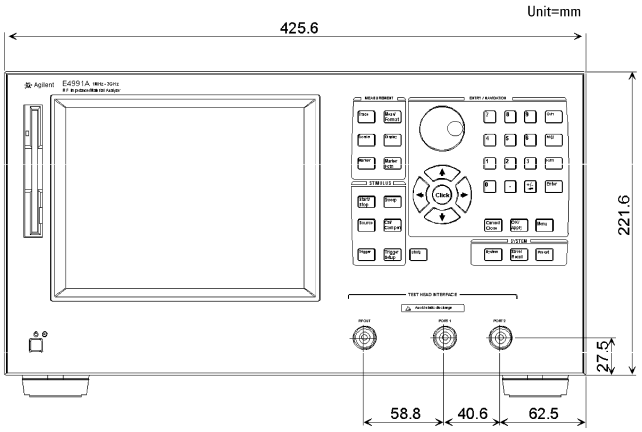

Figure 7. Main unit dimensions (front view, in millimeters, nominal)

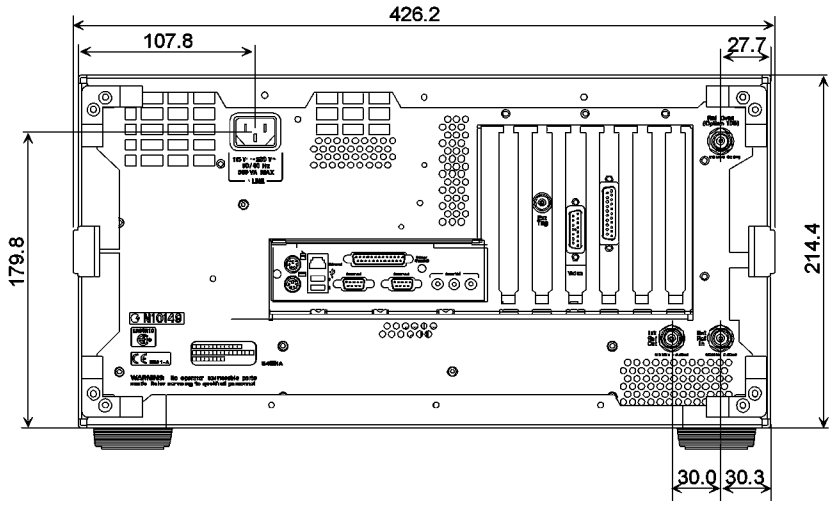

Figure 8. Main unit dimensions (rear view, in millimeters, nominal)

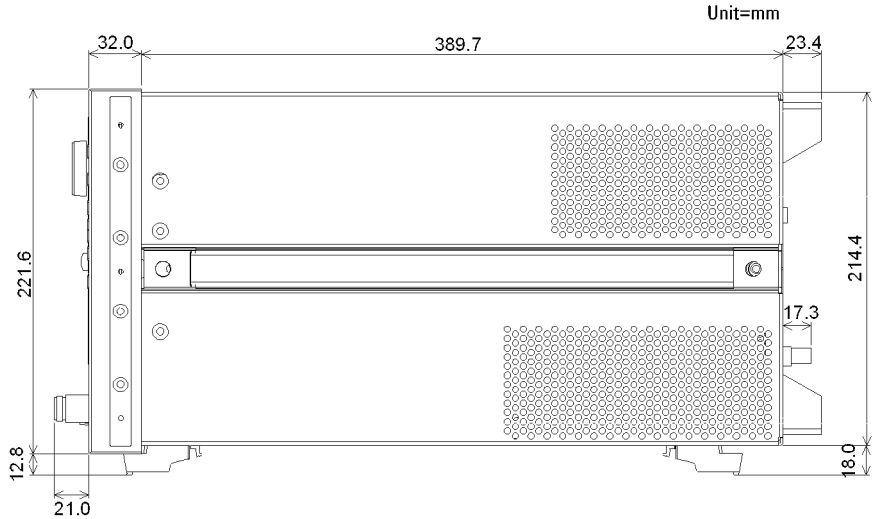

Figure 9. Main unit dimensions (side view, in millimeters, nominal)

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General Characteristics *(continued)*

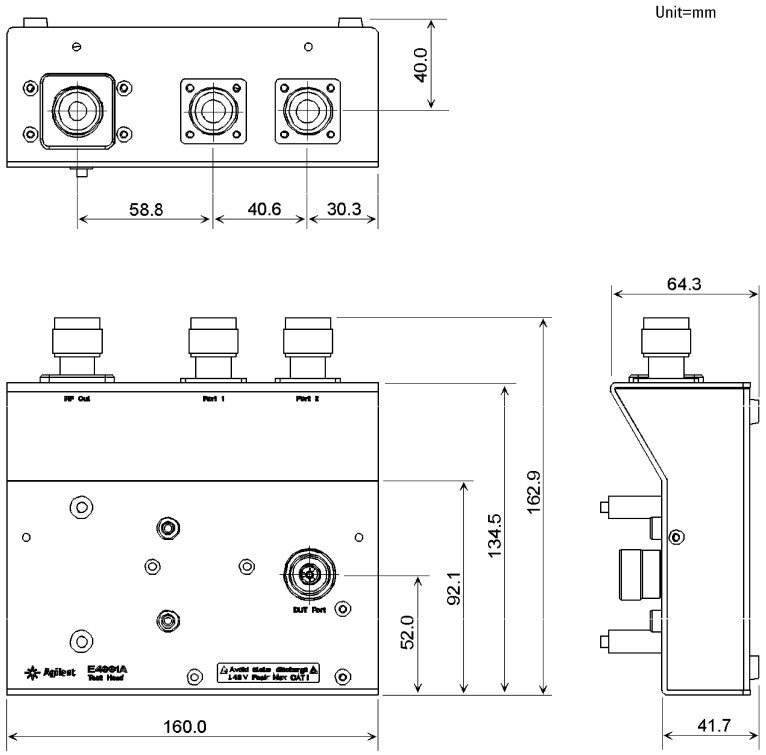

Figure 10. Test head dimensions (in millimeters, nominal)

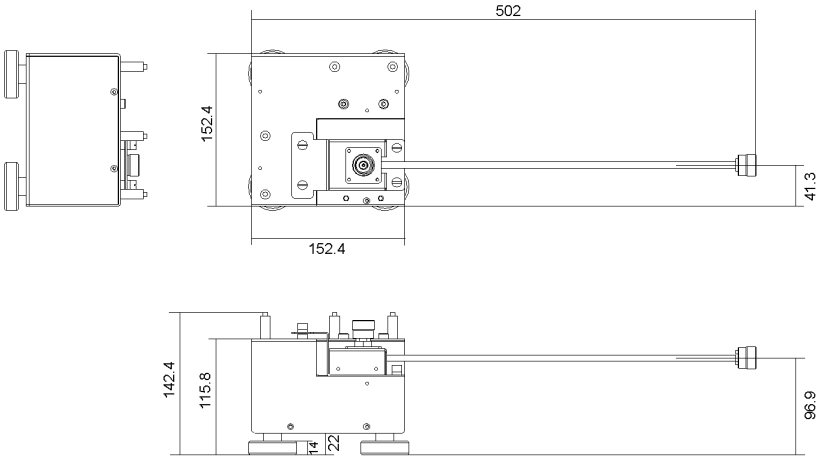

Figure 11. Option E4991A-007 test head dimensions (in millimeters,nominal)

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General Characteristics *(continued)*

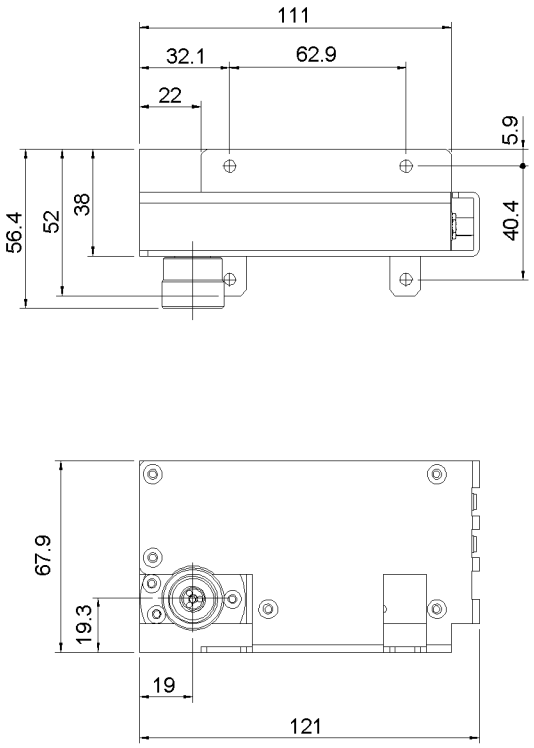

Figure 12. Option E4991A-010 test head dimensions (in millimeters,nominal)

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Furnished accessories

Model/option number	Description	Quantity
Agilent E4991A	Agilent E4991A impedance/material analyzer (main unit)	1
	Test head	1
	Agilent 16195B 7-mm calibration kit	1
	Torque wrench	1
	E4991A recovery disk	1
	Power cable	1
	CD-ROM (English/Japanese PDF manuals)[4]	1

4. The CD-ROM includes an operation manual, an installation and quick start guide, and a programming manual. A service manual is not included.

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Option E4491A-002 Material Measurement (Typical)

Measurement parameter

Permittivity parameters:
$|\varepsilon_r|$, ε_r', ε_r'', tanδ

Permeability parameters:
$|\mu_r|$, μ_r', μ_r'', tanδ

Frequency range

Using with Agilent 16453A:
1 MHz to 1 GHz (typical)

Using with Agilent 16454A:
1 MHz to 1 GHz (typical)

Measurement accuracy

Conditions for defining accuracy:

Calibration:
Open, short, and load calibration at the test port (7-mm connector)

Calibration temperature:
Calibration is performed at an environmental temperature within the range of 23 °C ± 5 °C. Measurement error doubles when calibration temperature is below 18 °C or above 28 °C.

Temperature:
Temperature deviation: within ±5 ˚C from the calibration temperature
Environment temperature: Measurement accuracy applies when the calibration is performed at 23 °C ±5 °C. When the calibration is below 18 °C or above 23 °C, measurement error doubles.

Measurement frequency points:
Same as calibration points

Oscillator level:
Same as the level set at calibraiton

Point averaging factor: ≥ 8

Electrode pressure setting of 16453A: maximum

Typical accuracy of permittivity parameters:

ε_r' accuracy $\left(=\frac{\Delta\varepsilon'_{rm}}{\varepsilon'_{rm}}\right)$:

$$\pm\left[5+\left(10+\frac{0.1}{f}\right)\frac{t}{\varepsilon'_{rm}}+0.25\,\frac{\varepsilon'_{rm}}{t}+\frac{100}{\left|1-\left(\frac{13}{f\sqrt{\varepsilon'_{rm}}}\right)^2\right|}\right][\%]$$

(at tanδ < 0.1)

Loss tangent accuracy of ε_r (= Δtanδ):
$\pm(E_a + E_b)$ (at tanδ <0.1)

where,

E_a =

at Frequency ≤ 1 GHz:

$$0.002+\frac{0.001}{f}\bullet\frac{t}{\varepsilon'_{rm}}+0.004f+\frac{0.1}{\left|1-\left(\frac{13}{f\sqrt{\varepsilon'_{rm}}}\right)^2\right|}$$

$$E_b = \left(\frac{\Delta\varepsilon'_{rm}}{\varepsilon'_{rm}}\bullet\frac{1}{100}+\varepsilon'_{rm}\frac{0.002}{t}\right)\tan\delta$$

f = Measurement frequency [GHz]

t = Thickness of MUT (material under test) [mm]

ε'_{rm} = Measured value of ε'_r

tanδ = Measured value of dielectric loss tangent

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Typical accuracy of permeability parameters:

μ_r' accuracy $\left(= \frac{\Delta\mu'_{rm}}{\mu'_{rm}}\right)$:

$$4 + \frac{0.02}{f} \times \frac{25}{F\mu'_{rm}} + F\mu'_{rm}\left[1 + \frac{15}{F\mu'_{rm}}\right]^2 f^2\,[\%]$$

(at tanδ <0.1)

Loss tangent accuracy of $\dot{\mu}_r$ (= Δtanδ):

$\pm(E_a + E_b)$ (at tanδ <0.1)

where,

$$E_a = 0.002 + \frac{0.001}{F\mu'_{rm}f} + 0.004f$$

$$E_b = \frac{\Delta\mu_{rm}'}{\mu'_{rm}} \bullet \frac{\tan\delta}{100}$$

f = Measurement frequency [GHz]

F = $h\ln\frac{c}{b}$ [mm]

h = Height of MUT (material under test) [mm]

b = Inner diameter of MUT (material under test) [mm]

c = Outer diameter of MUT (material under test) [mm]

μ'_{rm} = Measured value of μ'_r

tanδ = Measured value of loss tangent

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Option E4491A-002 Material Measurement (typical)

(continued)

Examples of calculated permittivity measurement accuracy

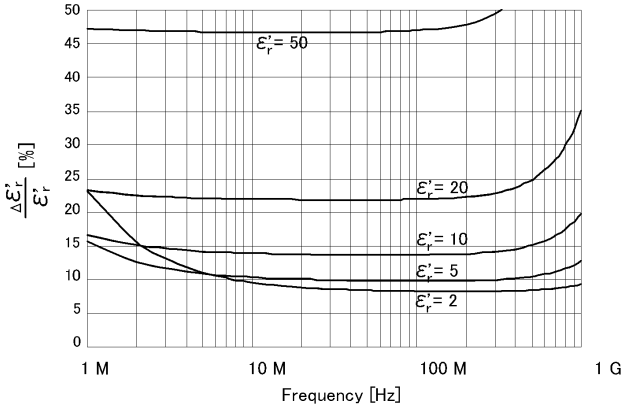

Figure 13. Permittivity accuracy $\frac{(\Delta\varepsilon'_r)}{\varepsilon'_r}$ vs. frequency (at t = 0.3 mm, typical)

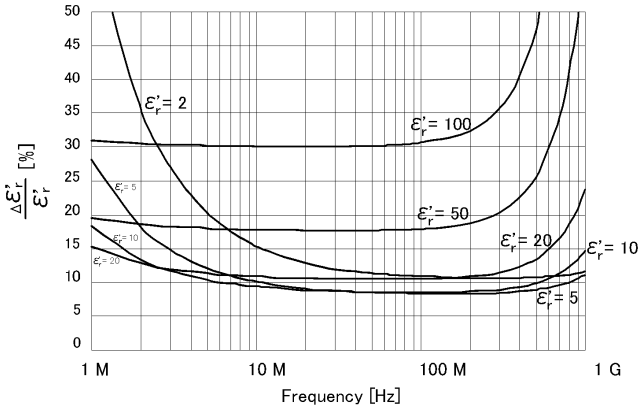

Figure 14. Permittivity accuracy $\frac{(\Delta\varepsilon'_r)}{\varepsilon'_r}$ vs. frequency (at t = 1 mm, typical)

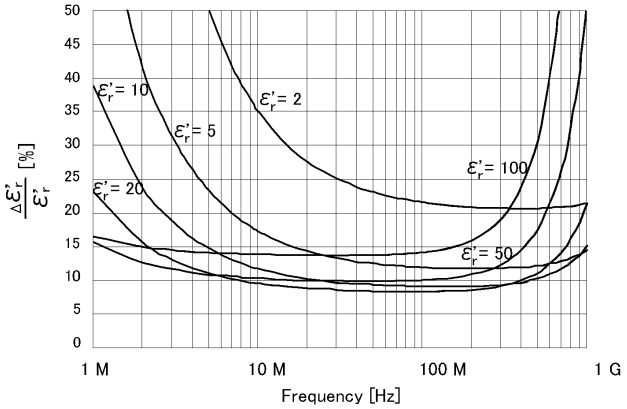

Figure 15. Permittivity accuracy $\frac{(\Delta\varepsilon'_r)}{\varepsilon'_r}$ vs. frequency (at t = 3 mm, typical)

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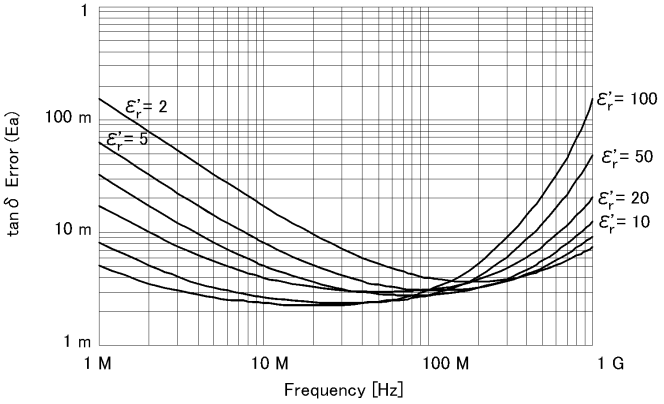

Figure 16. Dielectric loss tangent (tanδ) accuracy vs. frequency (at *t* = 0.3 mm, typical)[8]

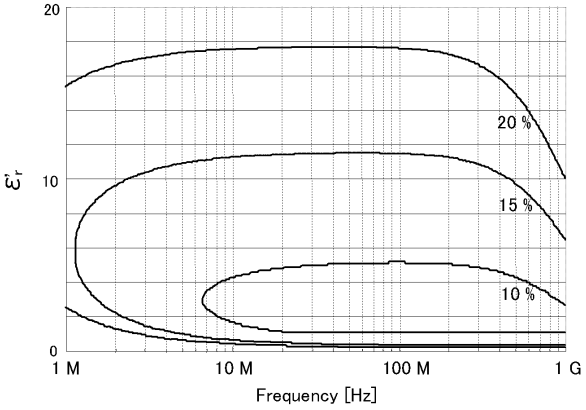

Figure 19. Permittivity (ε'_r) vs. frequency (at *t* = 0.3 mm, typical)

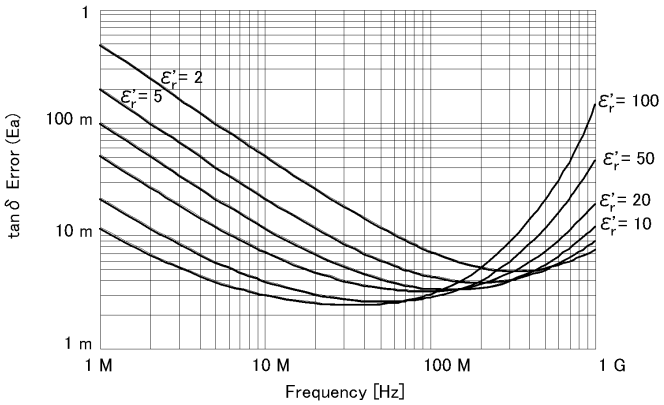

Figure 17. Dielectric loss tangent (tanδ) accuracy vs. frequency (at *t* = 1 mm, typical)[8]

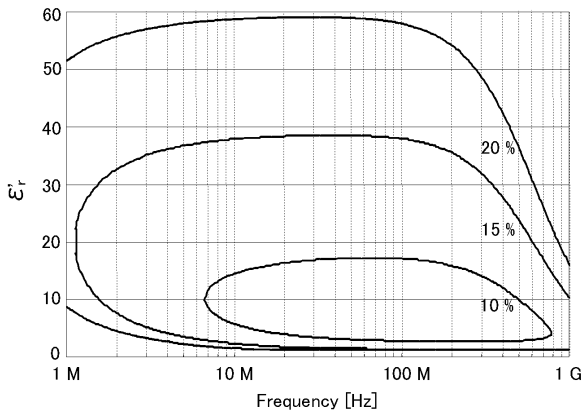

Figure 20. Permittivity (ε'_r) vs. frequency (at *t* = 1 mm, typical)

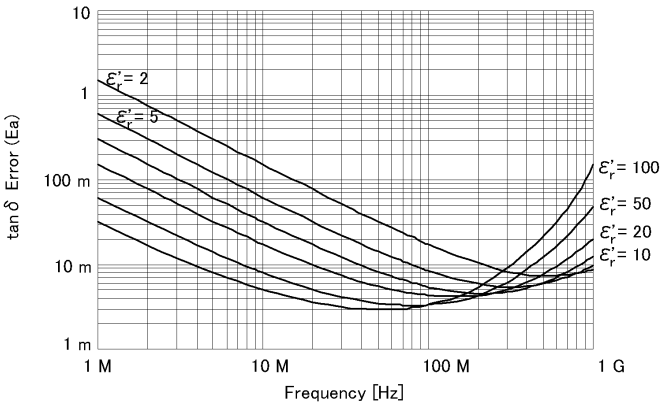

Figure 18. Dielectric loss tangent (tanδ) accuracy vs. frequency (at *t* = 3 mm, typical)[8]

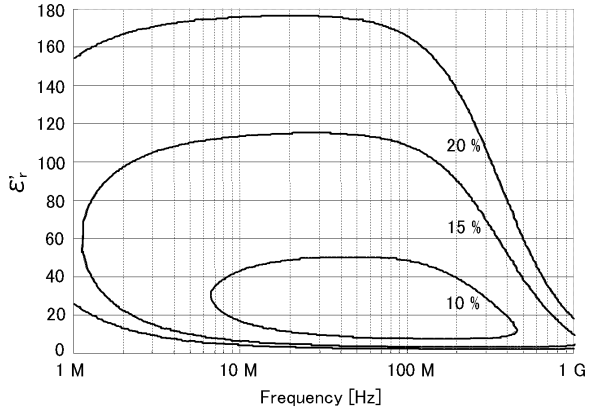

Figure 21. Permittivity (ε'_r) vs. frequency (at *t* = 3 mm, typical)

8. This graph shows only frequency dependence of E_a to simplify it. The typical accuracy of tanδ is defined as $E_a + E_b$; refer to *"Typical accuracy of permittivity parameters"* on page 17.

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Option E4991A-002 Material Measurement (typical)
(continued)

Examples of calculated permeability measurement accuracy

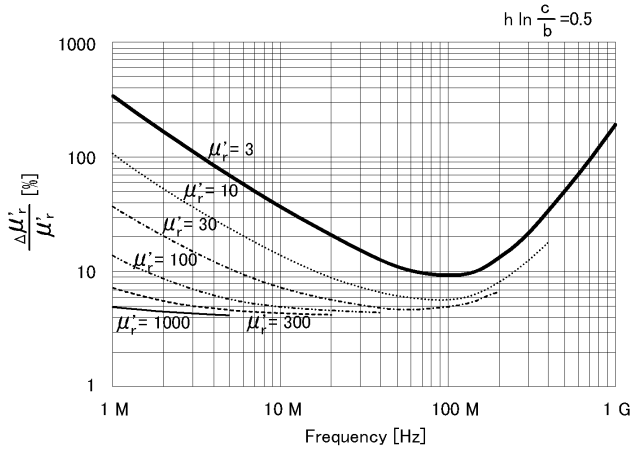

Figure 22. Permeability accuracy $\frac{(\Delta\mu'_r)}{\mu'_r}$ vs. frequency (at $F = 0.5$, typical)

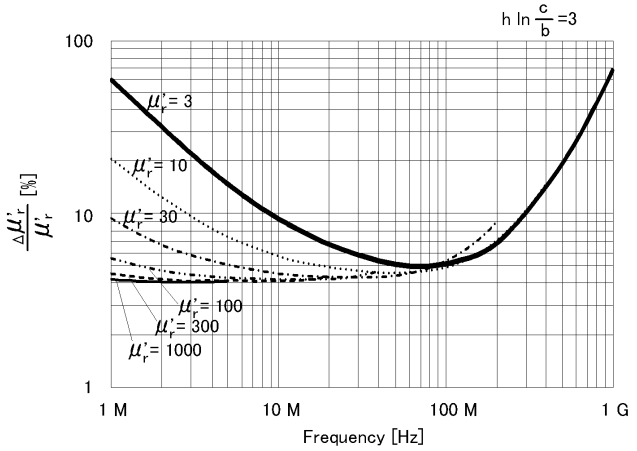

Figure 23. Permeability accuracy $\frac{(\Delta\mu'_r)}{\mu'_r}$ vs. frequency (at $F = 3$, typical)

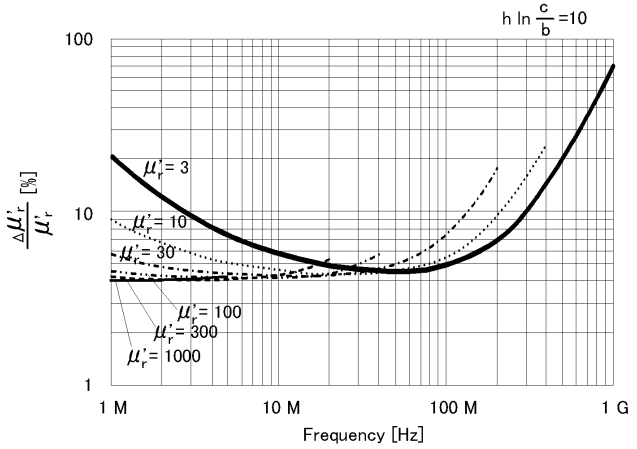

Figure 24. Permeability accuracy $\frac{(\Delta\mu'_r)}{\mu'_r}$ vs. frequency (at $F = 10$, typical)

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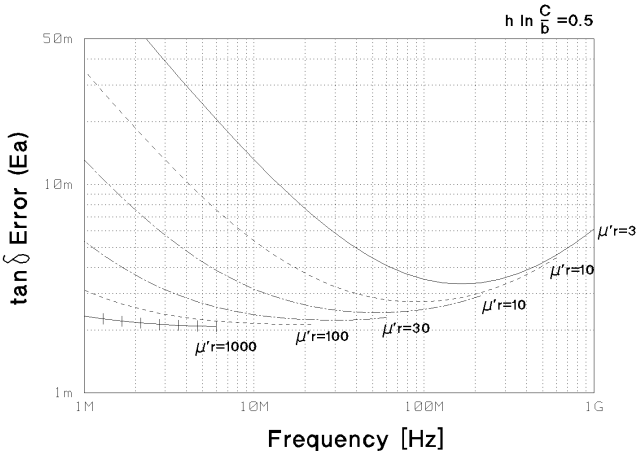

Figure 25. Permeability loss tangent (tanδ) accuracy vs. Frequency (at *F* = 0.5, typical)[9]

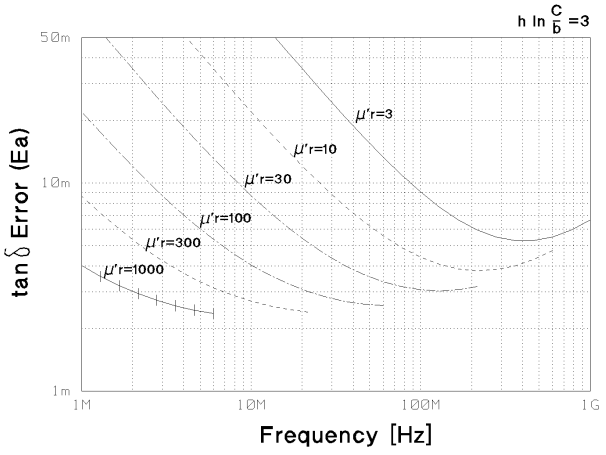

Figure 26. Permeability loss tangent (tanδ) accuracy vs. frequency (at *F* = 3, typical)[9]

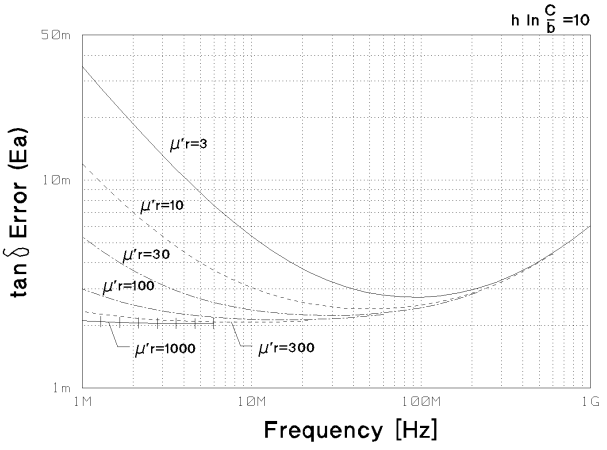

Figure 27. Permeability loss tangent (tanδ) accuracy vs. frequency (at *F* = 10, typical)[9]

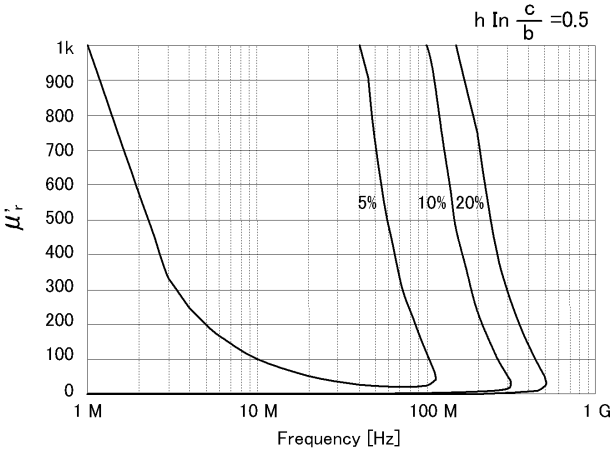

Figure 28. Permeability (μ'_r) vs. frequency (at *F* = 0.5, typical)

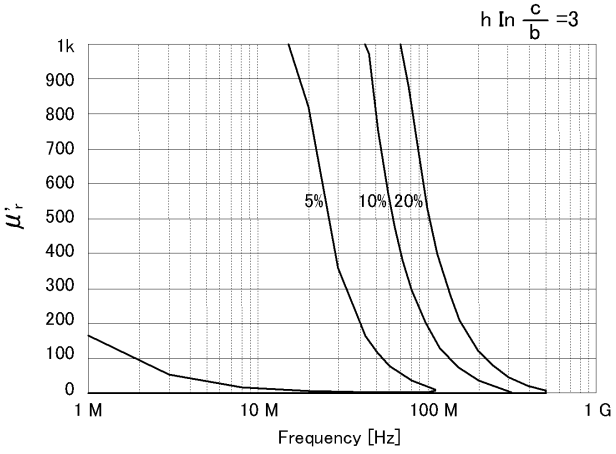

Figure 29. Permeability (μ'_r) vs. frequency (at *F* = 3, typical)

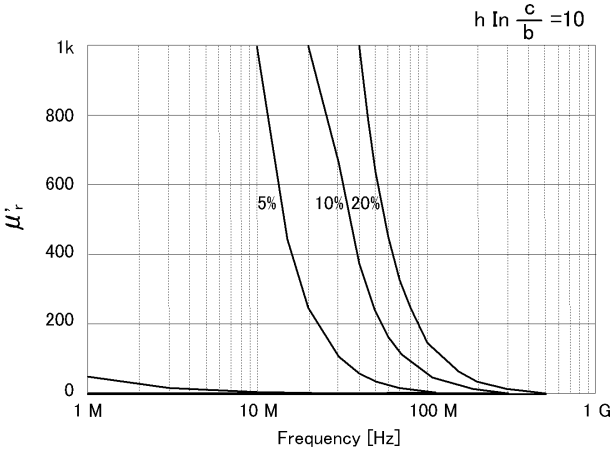

Figure 30. Permeability (μ'_r) vs. frequency (at *F* = 10, typical)

9. This graph shows only frequency dependence of E_a to simplify it. The typical accuracy of tanδ is defined as $E_a + E_b$; refer to *"Typical accuracy of permeability parameters"* on page 18.

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Option E4991A-007 Temperature Characteristic Test Kit

This section contains specifications and supplemental information for the E4991A Option E4991A-007. Except for the contents in this section, the E4991A standard specifications and supplemental information are applied.

Operation temperature

Range:

–55 °C to +150 °C (at the test port of the high temperature cable)

Source characteristics

Frequency

Range:

1 MHz to 3 GHz

Oscillator level

Source power accuracy at the test port of the high temperature cable:

Frequency ≤ 1 GHz:
+2 dB/–4 dB (23 °C ±5 °C)
+4 dB/–6 dB (5 °C to 40 °C)

Frequency > 1 GHz:
+3 dB/–6 dB (23 °C ±5 °C)
+5 dB/–8 dB (5 °C to 40 °C)

Measurement accuracy (at 23 °C ±5 °C)

Conditions[10]

The measurement accuracy is specified when the following conditions are met:

Calibration: open, short and load calibration is completed at the test port (7-mm connector) of the high temperature cable

Calibration temperature: calibration is performed at an environmental temperature within the range of 23 °C ±5 °C. Measurement error doubles when calibration temperature is below 18 °C or above 28 °C.

Measurement temperature range: within ±5 °C of calibration temperature

Measurement plane: same as calibration plane

Oscillator level: same as the level set at calibration

Impedance, admittance and phase angle accuracy:

|Z|, |Y| ± (E_a + E_b) [%]
(see Figure 31 through Figure 34 for calculated accuracy)

θ $\pm\frac{(E_a + E_b)}{100}$ [rad]

where,

E_a = at oscillator level ≥ –33 dBm:
±0.8 [%] (1 MHz ≤ f ≤ 100 MHz)
±1 [%] (100 MHz < f ≤ 500 MHz)
±1.2 [%] (500 MHz < f ≤ 1 GHz)
±2.5 [%] (1 GHz < f ≤ 1.8 GHz)
±5 [%] (1.8 GHz < f ≤ 3 GHz)

at oscillator level ≥ –33 dBm:
±1.2 [%] (1 MHz ≤ f ≤ 100 MHz)
±1.5 [%] (100 MHz < f ≤ 500 MHz)
±1.5 [%] (500 MHz < f ≤ 1 GHz)
±2.5 [%] (1 GHz < f ≤ 1.8 GHz)
±5 [%] (1.8 GHz < f ≤ 3 GHz)
(Where, f is frequency)

E_b = $\pm\left(\frac{Z_s}{|Z_x|} + Y_o \times |Z_x|\right)\times 100$ [%]

Where,

$|Z_x|$ = Absolute value of impedance

Z_s = At oscillator level = –3 dBm, –13 dBm, or –23 dBm:
± (30 + 0.5 × F) [mΩ] (point averaging factor ≥ 8)
± (40 + 0.5 × F) [mΩ] (point averaging factor ≤ 7)

At oscillator level ≥ –33 dBm:
± (35 + 0.5 × F) [mΩ] (point averaging factor ≥ 8)
± (70 + 0.5 × F) [mΩ] (point averaging factor ≤ 7)

At oscillator level < –33 dBm:
± (50 + 0.5 × F) [mΩ] (point averaging factor ≥ 8)
± (150 + 0.5 × F) [mΩ] (point averaging factor ≤ 7)

(Where, F is frequency in MHz)

Y_o = At oscillator level = –3 dBm, –13 dBm, –23 dBm:
± (12 + 0.1 × F) [μS] (point averaging factor ≥ 8)
± (20 + 0.1 × F) [μS] (point averaging factor ≤ 7)

At oscillator level ≥ –33 dBm:
± (15 + 0.1 × F) [μS] (point averaging factor ≥ 8)
± (40 + 0.1 × F) [μS] (point averaging factor ≤ 7)

At oscillator level < –33 dBm:
± (35 + 0.1 × F) [μS] (point averaging factor ≥ 8)
± (80 + 0.1 × F) [μS] (point averaging factor ≤ 7)

(Where, F is frequency in MHz)

10. The high temperature cable must be kept at the same position throughout calibration and measurement.

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Calculated Impedance/ Admittance Measurement Accuracy

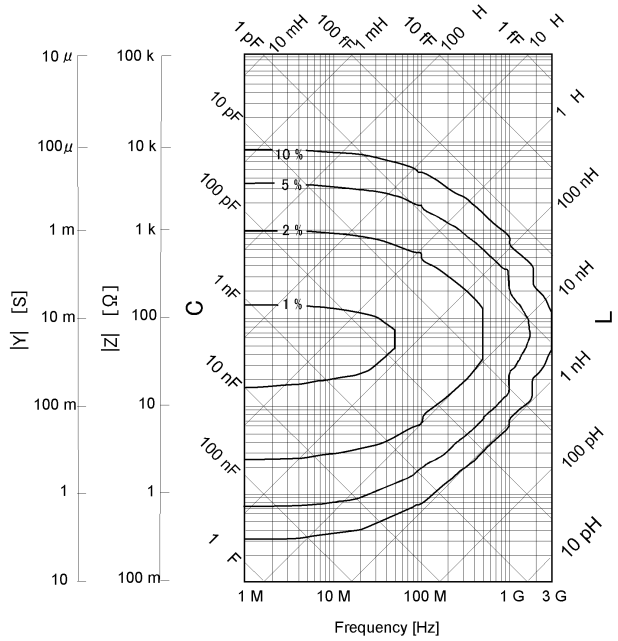

Figure 31. |Z|, |Y| measurement accuracy when open/short/load calibration is performed. Oscillator level = –23 dBm, –13 dBm, –3 dBm. Point averaging factor ≥ 8 within ±5 °C of calibration temperature.

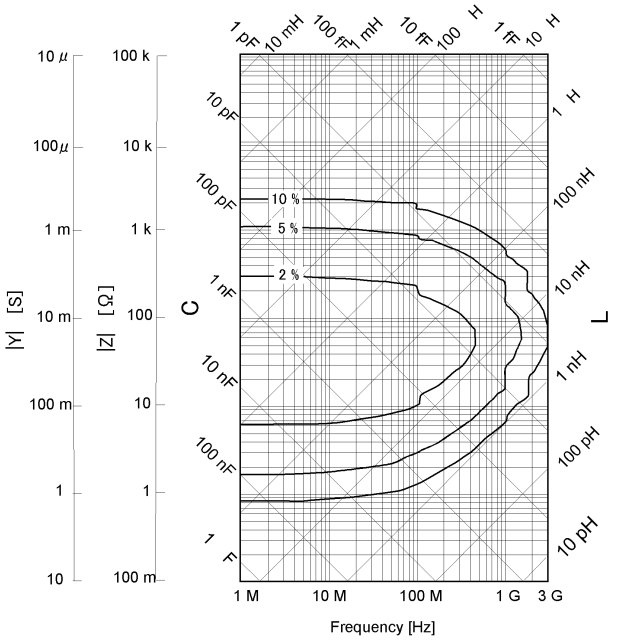

Figure 33. |Z|, |Y| measurement accuracy when open/short/load calibration is perfomed. Oscillator level ≥ –33 dBm. Point averaging factor ≤ 7 within ±5 °C of calibration temperature.

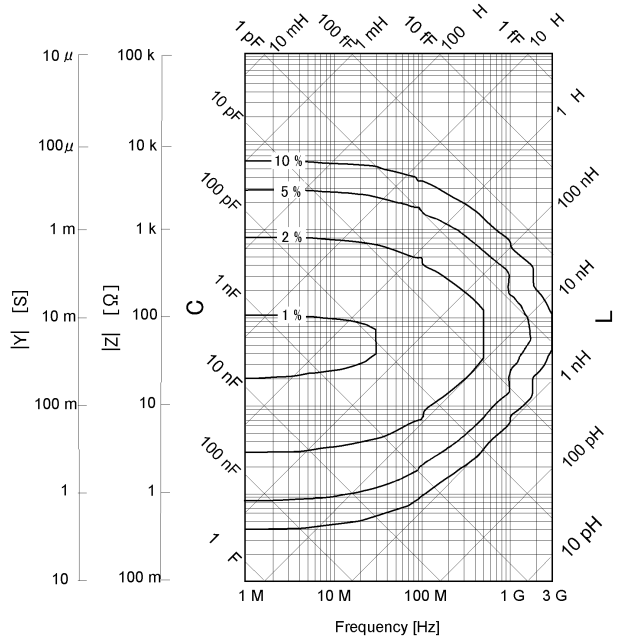

Figure 32. |Z|, |Y| measurement accuracy when open/short/load calibration is performed. Oscillator level ≥ –33 dBm. Point averaging factor ≥ 8 within ±5 °C of calibration temperature.

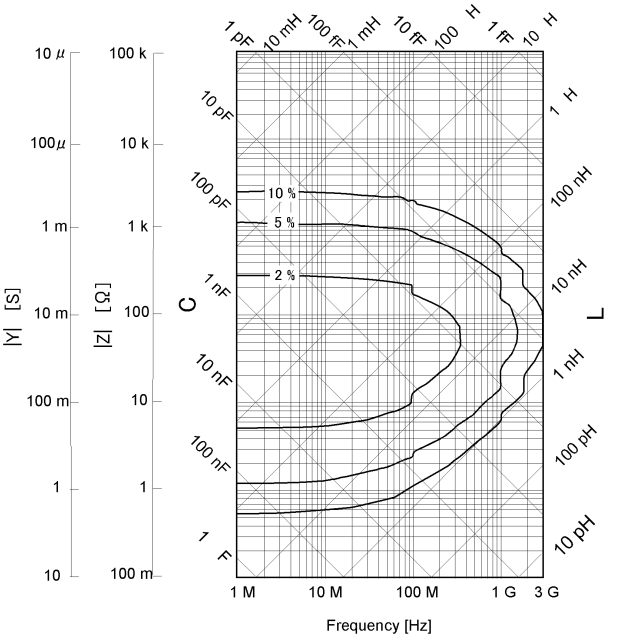

Figure 34. |Z|, |Y| measurement accuracy when open/short/load calibration is performed. Oscillator level < –33 dBm. Point averaging factor ≥ 8 within ±5 °C of calibration temperature.

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Typical Effects of Temperature Change on Measuement Accuracy

When the temperature at the test port (7-mm connector) of the high temperature cable changes from the calibration temperature, typical measurement accuracy involving temperature dependence effects (errors) is applied. The typical measurement accuracy is represented by the sum of error due to temperature coefficients ($E_a´$, $Y_o´$ *and* $Z_s´$), hysteresis error (E_{ah}, Y_{oh} and Z_{sh}) and the specified accuracy.

Conditions

The typical measurement accuracy is applied when the following conditions are met:

Conditions of E_a', Z_s' and Y_o':

Measurement temperature: –55 °C to 5 °C or 40 °C to 150 °C at test port. For 5 °C to 40 °C, $E_a´$, $Y_o´$ and $Z_s´$ are 0 (neglected).

Temperature change: ≥ 5 °C from calibration temperature when the temperature compensation is off.
≥ 20 °C from calibration temperature when the temperature compensation is set to on.

Calibration temperature: 23 °C ±5 °C

Calibration mode: user calibration

Temperature compensation: temperature compensation data is acquired at the same temperature points as measurement temperatures.

Conditions of E_{ah}, Z_{sh} and Y_{oh}:

Measurement temperature: –55 °C to 150 °C at the test port

Calibration temperature: 23 °C ±5 °C

Calibration mode: user calibration

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Typical measurement accuracy (involving temperature dependence effects)[11]:

$|Z|, |Y|: \pm (E_a + E_b + E_c + E_d)$ [%]

$\theta : \pm \dfrac{(E_a + E_b + E_c + E_d)}{100}$ [rad]

Where,

$E_c = E_a' \times \Delta T + E_{ah}$

$E_d = \pm \left\{ \dfrac{Z_s' \times \Delta T + Z_{sh}}{|Z_x|} + (Y_o' \times \Delta T + Y_{oh}) \times |Z_x| \times \right\} 100$ [%]

Where,

$|Z_x|$ = Absolute value of measured impedance

Here, E_a', Z_s' and Y_o' are given by the following equations:

	Without temperature compensation	**With temperature compensation**	
		1 MHz ≤ f < 500 MHz	500 MHz ≤ f ≤ 3 GHz
E_a'	0.006 + 0.015 × f [%/°C]	0.006 + 0.015 × f [%/°C]	0.006 + 0.015 × f [%/°C]
Z_s'	1 + 10 × f [mΩ/°C]	1 + 10 × f [mΩ/°C]	5 + 2 × f [mΩ/°C]
Y_o'	0.3 + 3 × f [µS/°C]	0.3 + 3 × f [µS/°C]	1.5 + 0.6 × f [µS/°C]

f = Measurement frequency in GHz

E_{ah}, Z_{sh} and Y_{oh} are given by following equations:

$E_{ah} = E_a' \times \Delta T_{max} \times 0.3$ [%]

$Z_{sh} = Z_s' \times \Delta T_{max} \times 0.3$ [mΩ]

$Y_{oh} = Y_o' \times \Delta T_{max} \times 0.3$ [µS]

ΔT = Difference of measurement temperature from calibration temperature

ΔT_{max} = Maximum temperature change (°C) at the test port from calibration temperature after the calibration is performed.

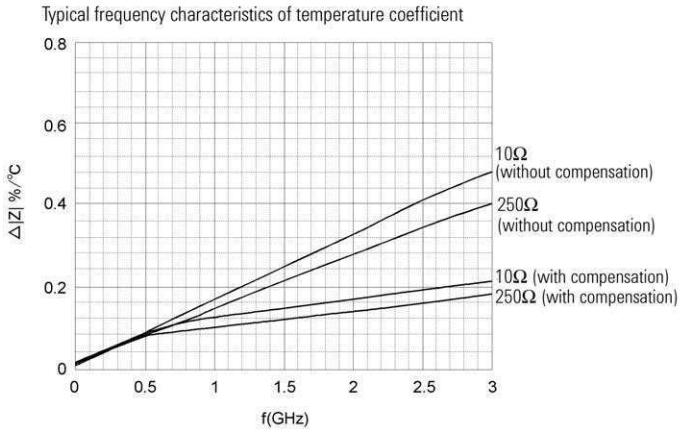

Figure 35. Typical frequency characteristics of temperature coefficient, (Ec+Ed)/ΔT, when |Zx| = 10 Ω and 250 Ω, E_{ah}= Z_{sh}= Y_{oh}= 0 are assumed[12].

11. See graphs in Figure 35 for the calculated values of (Ec+Ed) exclusive of the hysteresis errors E_{ah}, Z_{sh} and Y_{oh}, when measured impedance is 10 Ω and 250 Ω.
12. Read the value of Δ|Z|%/°C at the material measurement frequency and multiply it by ΔT to derive the value of (Ec+Ed) when E_{ah}= Y_{oh}= Z_{sh}= 0.

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Typical Material Measurement Accuracy When Using Options E4991A-002 and E4991A-007

Material measurement accuracy contains the permittivity and permeability measurement accuracy when the E4991A with Option E4991A-002 and E4991A-007 is used with the 16453A or 16454A test fixture.

Measurement parameter

Permittivity parameters:
$|\varepsilon_r|$, ε'_r, ε'', tanδ

Permeability parameters:
$|\mu_r|$, μ'_r, μ'', tanδ

Frequency

Use with Agilent 16453A:
1 MHz to 1 GHz (typical)

Use with Agilent 16454A:
1 MHz to 1 GHz (typical)

Opertation temperature

Range:
–55 °C to +150 °C (at the test port of the high temperature cable)

Typical material measurement accuracy (at 23 °C ±150 °C)

Conditions
The measurement accuracy is specified when the following conditions are met:

Calibration: Open, short and load calibration is completed at the test port (7-mm connector) of the high temperature cable

Calibration temperature: Calibration is performed at an environmental temperature within the range of 23 °C ±5 °C. Measurement error doubles when calibration temperature is below 18 °C or above 28 °C.

Measurement temperature range: Within ±5 °C of calibration temperature

Measurement frequency points: Same as calibration points (User Cal)

Oscillator level: Same as the level set at calibration

Point averaging factor: ≥ 8

Typical permittivity measurement accuracy[13]:

ε_r' accuracy $\left(E_\varepsilon = \frac{\Delta\varepsilon'_{rm}}{\varepsilon'_{rm}}\right)$:

$$\pm\left[5+\left(10+\frac{0.5}{f}\right)\times\frac{t}{\varepsilon'_{rm}}+0.25\times\frac{\varepsilon'_{rm}}{t}+\frac{100}{\left|1-\left(\frac{13}{f\sqrt{\varepsilon'_{rm}}}\right)^2\right|}\right]$$

[%] (at tanδ < 0.1)

Loss tangent accuracy of $\dot{\varepsilon}_r$ (= Δtanδ) :

$\pm\,(E_a + E_b)$ (at tanδ < 0.1)

where,

E_a =

at Frequency ≤ 1 GHz

$$0.002+\frac{0.0025}{f}\times\frac{t}{\varepsilon'_{rm}}+(0.008\times f)+\frac{0.1}{\left|1-\left(\frac{13}{f\sqrt{\varepsilon'_{rm}}}\right)^2\right|}$$

$$E_b = \left(\frac{\Delta\varepsilon'_{rm}}{\varepsilon'_{rm}}\times\frac{1}{100}+\varepsilon'_{rm}\frac{0.002}{t}\right)\times\tan\delta$$

f = Measurement frequency [GHz]

t = Thickness of MUT (material under test) [mm]

ε'_{rm} = Measured value of ε'_r

tanδ = Measured value of dielectric loss tangent

13. The accuracy applies when the electrode pressure of the 16453A is set to maximum.

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Typical permeability measurement accuracy :

μ_r' accuracy $E_\mu = \left(\frac{\Delta \mu'_{rm}}{\mu'_{rm}} \right)$:

$$4 + \frac{0.02}{f} \times \frac{25}{F \times \mu'_{rm}} + F \times \mu'_{rm} \times \left[1 + \frac{15}{F \times \mu'_{rm}} \right]^2 \times f^2$$

[%] (at tanδ < 0.1)

Loss tangent accuracy of $\dot{\mu}_r$ (= Δtanδ) :

± (E_a + E_b) (at tanδ < 0.1)

where,

E_a = $0.002 + \frac{0.005}{\mathrm{F} \times \mu'_{rm} \times f} + 0.004 \times f$

E_b = $\frac{\Delta \mu'_{rm}}{\mu'_{rm}} \times \frac{\tan\delta}{100}$

f = Measurement frequency [GHz]

F = $h \ln \frac{c}{b}$ [mm]

h = Height of MUT (material under test) [mm]

b = Inner diameter of MUT [mm]

c = Outer diameter of MUT [mm]

μ'_{rm} = Measured value of μ'_r

tanδ = Measured value of loss tangent

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Examples of Calculated Permittivity Measurement Accuracy

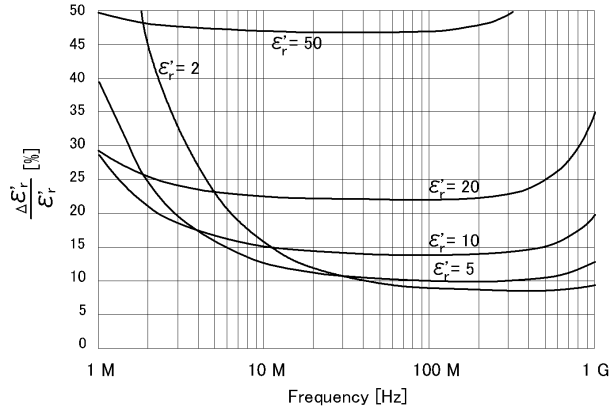

Figure 36. Permittivity accuracy $\frac{(\Delta\varepsilon'_r)}{\varepsilon'_r}$ vs. frequency (at t = 0.3 mm, typical)

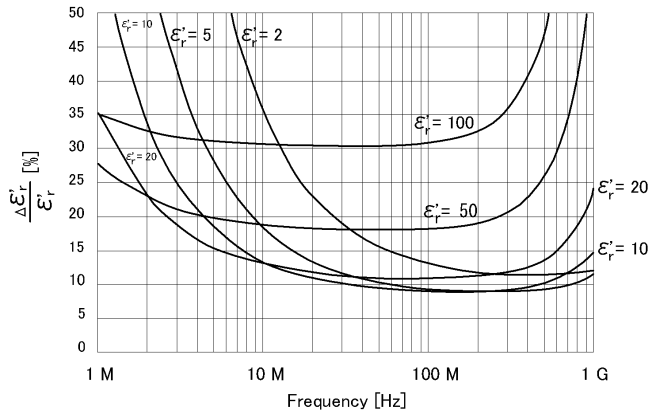

Figure 37. Permittivity accuracy $\frac{(\Delta\varepsilon'_r)}{\varepsilon'_r}$ vs. frequency (at t = 1 mm, typical)

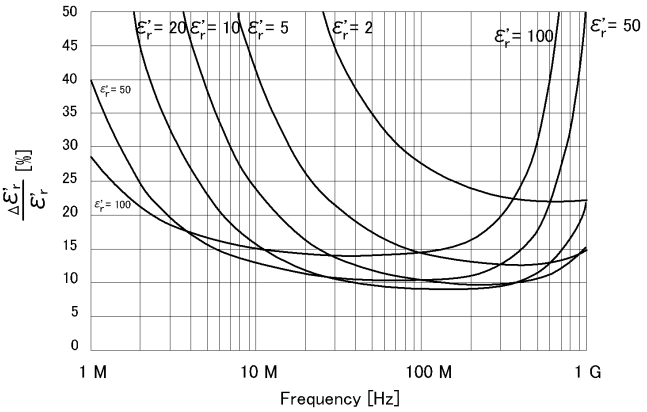

Figure 38. Permittivity accuracy $\frac{(\Delta\varepsilon'_r)}{\varepsilon'_r}$ vs. frequency (at t = 3 mm, typical)

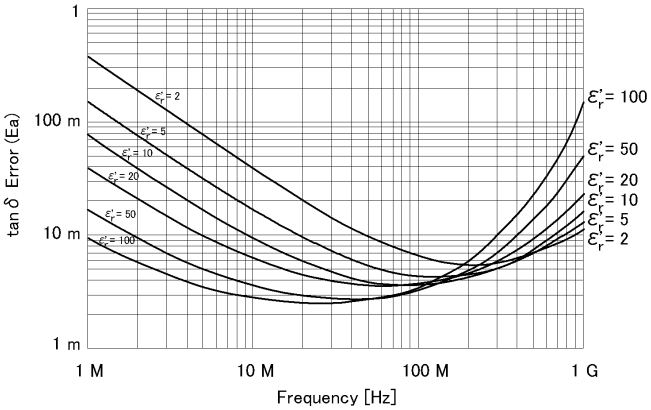

Figure 39. Dielectric loss tangent (tanδ) accuracy vs. frequency (at t = 0.3 mm, typical)[14]

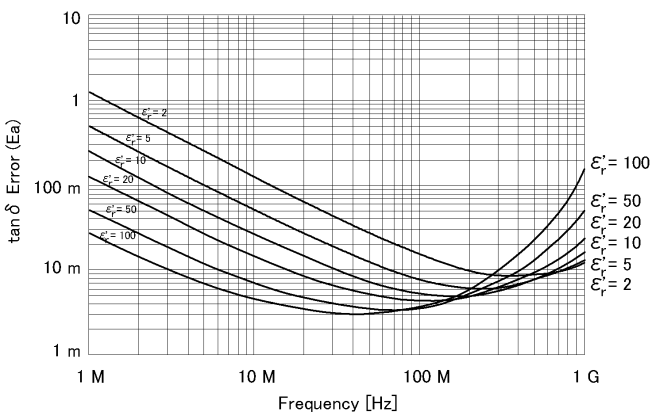

Figure 40. Dielectric loss tangent (tanδ) accuracy vs. frequency (at t = 1 mm, typical)[14]

14. This graph shows only frequency dependence of E_a for simplification. The typical accuracy of tanδ is defined as $E_a + E_b$; refer to *"Typical permittivity measurement accuracy"* on page 27.

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Examples of Calculated Permittivity Measurement Accuracy *(continued)*

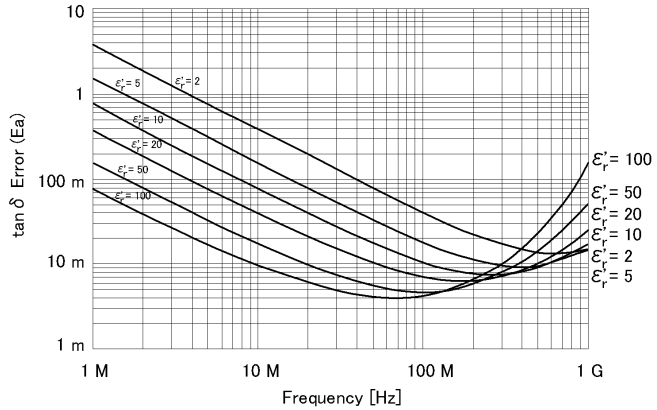

Figure 41. Dielectric loss tangent (tanδ) accuracy vs. frequency (at t = 3 mm, typical)[14]

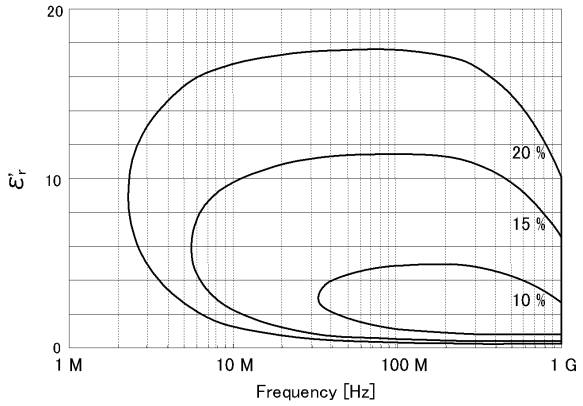

Figure 42. Permittivity (ε_r') vs. frequency (at t = 0.3 mm, typical)

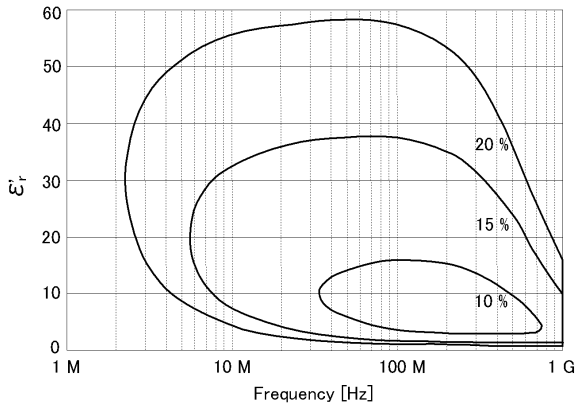

Figure 43. Permittivity (ε_r') vs. frequency (at t = 1 mm, typical)

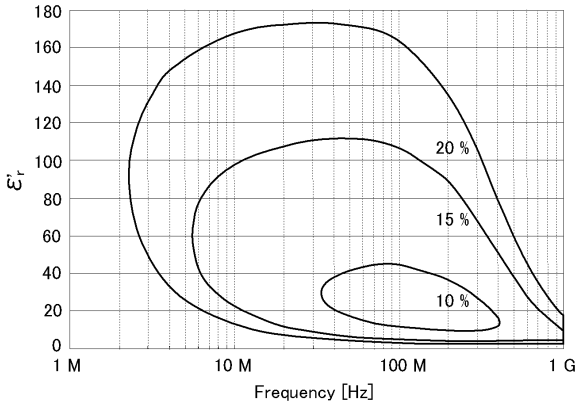

Figure 44. Permittivity (ε_r') vs. frequency (at t = 3 mm, typical)

14. This graph shows only frequency dependence of E_a for simplification. The typical accuracy of tanδ is defined as $E_a + E_b$; refer to *"Typical permittivity measurement accuracy"* on page 27.

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Examples of Calculated Permeability Measurement Accuracy

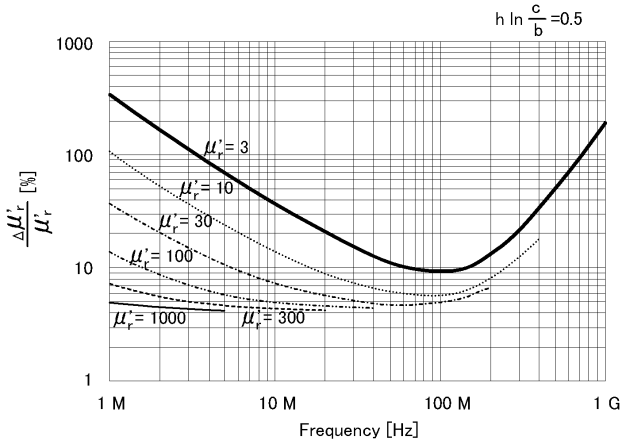

Figure 45. Permeability accuracy $\frac{(\Delta\mu'_r)}{\mu'_r}$ vs. frequency (at $F = 0.5$, typical)

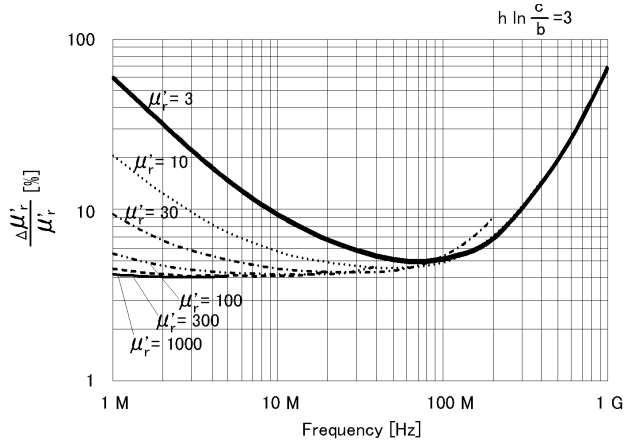

Figure 46. Permeability accuracy $\frac{(\Delta\mu'_r)}{\mu'_r}$ vs. frequency (at $F = 3$, typical)

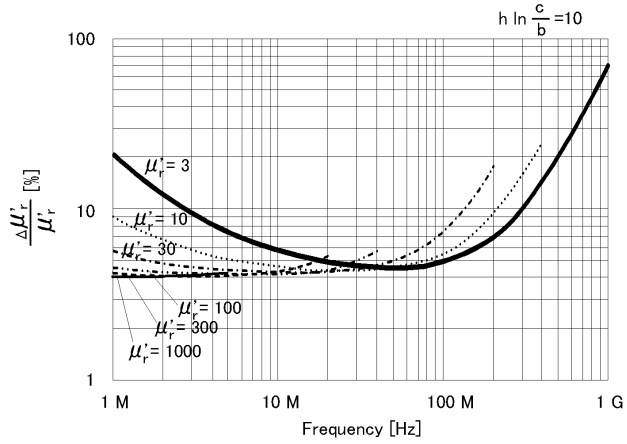

Figure 47. Permeability accuracy $\frac{(\Delta\mu'_r)}{\mu'_r}$ vs. frequency (at $F = 10$, typical)

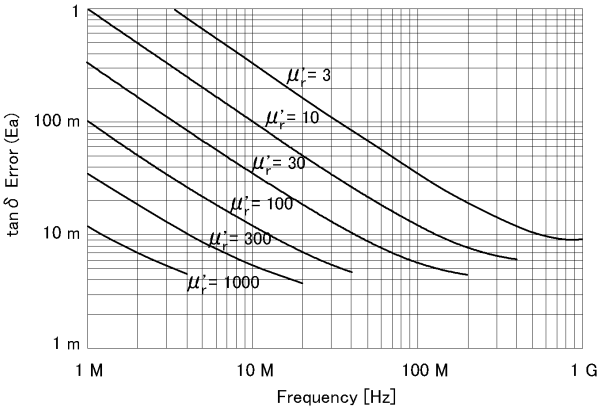

Figure 48. Permeability loss tangent (tanδ) accuracy vs. Frequency (at $F = 0.5$, typical)[15]

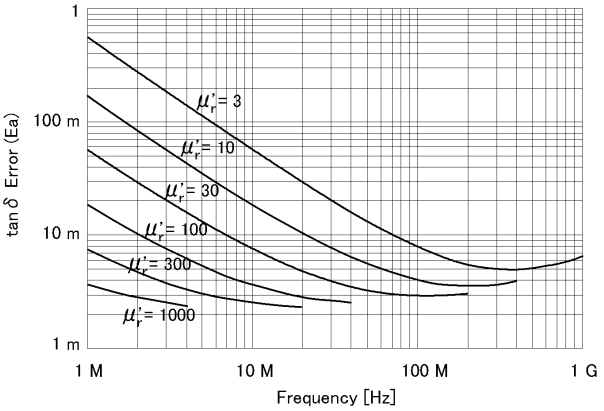

Figure 49. Permeability loss tangent (tanδ) accuracy vs. Frequency (at $F = 3$, typical)[15]

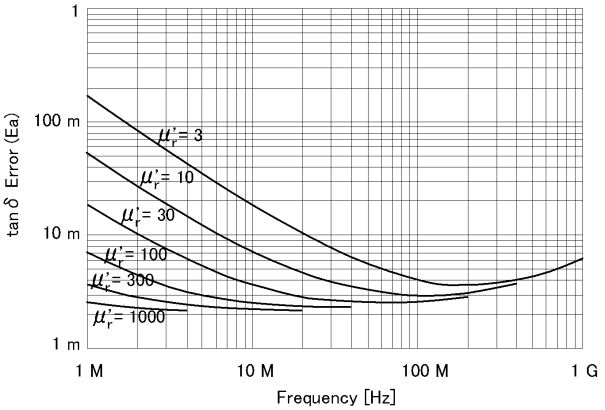

Figure 50. Permeability loss tangent (tanδ) accuracy vs. Frequency (at $F = 10$, typical)[15]

15. This graph shows only frequency dependence of E_a for simplification. The typical accuracy of tanδ is defined as $E_a + E_b$; refer to *"Typical permeability measurement accuracy"* on page 28.

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Examples of Calculated Permeability Measurement Accuracy *(continued)*

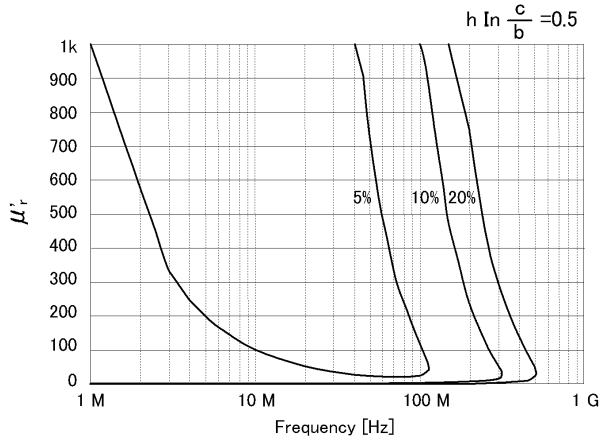

Figure 51. Permeability (μ'_r) vs. frequency (at $F = 0.5$, typical)

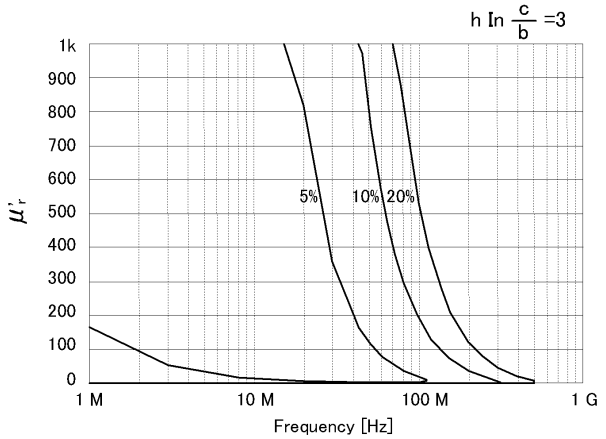

Figure 52. Permeability (μ'_r) vs. frequency (at $F = 3$, typical)

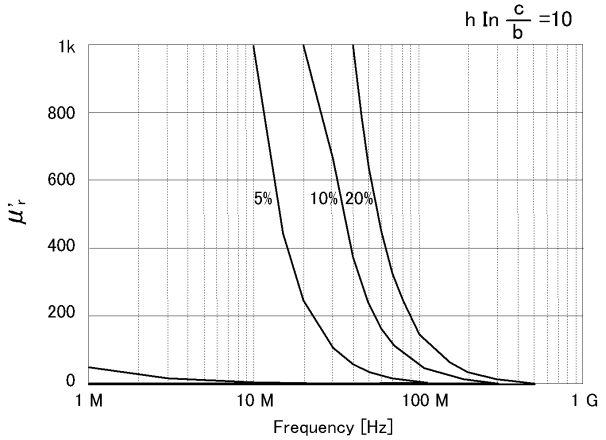

Figure 53. Permeability (μ'_r) vs. frequency (at $F = 10$, typical)

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Typical Effects of Temperature Change on Permittivity Measurement Accuracy

When the temperature at the test port (7-mm connector) of the high temperature cable changes more than 5 °C from the calibration temperature, the typical permittivity measurement accuracy involving temperature dependence effects (errors) is applied. The typical permittivity accuracy is represented by the sum of error due to temperature coefficient (T_c), hysteresis error ($T_c \times \Delta T_{max}$) and the accuracy at 23 °C ± 5 °C.

Typical accuracy of permittivity parameters:

ε_r' accuracy $= \left[\frac{\Delta\varepsilon'_{rm}}{\varepsilon'_{rm}}\right]$:

$\pm (E_\varepsilon + E_f + E_g)$ [%]

Loss tangent accuracy of $\dot{\varepsilon}$ (= $\Delta\tan\delta$) :

$$\pm \frac{(E_\varepsilon + E_f + E_g)}{100}$$

where,

E_ε = Permittivity measurement accuracy at 23 °C ± 5 °C

$E_f = T_c \times \Delta T$

$E_g = T_c \times \Delta T_{max} \times 0.3$

$Tc = K_1 + K_2 + K_3$

See Figure 54 through Figure 56 for the calculated value of T_c without temperature compensation

$K_1 = 1 \times 10^{-6} \times (60 + 150 \times f)$

$K_2 =$

$$3 \times 10^{-6} \times (1 + 10 \times f) \times \left(\frac{\varepsilon'_{rm}}{t} \times \left| \frac{1}{1 - \left[\frac{f}{f_o}\right]^2} \right| + 10 \right) \times f$$

$K_3 =$

$$5 \times 10^{-3} \times (0.3 + 3 \times f) \times \frac{1}{\left(\frac{\varepsilon'_{rm}}{t} \times \left| \frac{1}{1 - \left[\frac{f}{f_o}\right]^2} \right| + 10 \right) \times f}$$

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Typical accuracy of permittivity parameters (continued):

with temperature compensation

K_1 = $1 \times 10^{-6} \times (60 + 150 \times f)$

K_2 = 1 MHz ≤ f < 500 MHz

$$3 \times 10^{-6} \times (1 + 10 \times f) \times \left(\frac{\varepsilon'_{rm}}{t} \times \left| \frac{1}{1 - \left(\frac{f}{f_o} \right)^2} \right| + 10 \right) \times f$$

500 MHz ≤ f ≤ 1 GHz

$$3 \times 10^{-6} \times (5 + 2 \times f) \times \left(\frac{\varepsilon'_{rm}}{t} \times \left| \frac{1}{1 - \left(\frac{f}{f_o} \right)^2} \right| + 10 \right) \times f$$

K_3 = 1 MHz ≤ f < 500 MHz

$$5 \times 10^{-3} \times (0.3 + 3 \times f) \times \frac{1}{\left(\frac{\varepsilon'_{rm}}{t} \times \left| \frac{1}{1 - \left(\frac{f}{f_o} \right)^2} \right| + 10 \right) \times f}$$

500 MHz ≤ f ≤ 1 GHz

$$5 \times 10^{-3} \times (1.5 + 0.6 \times f) \times \frac{1}{\left(\frac{\varepsilon'_{rm}}{t} \times \left| \frac{1}{1 - \left(\frac{f}{f_o} \right)^2} \right| + 10 \right) \times f}$$

f = Measurement frequency [GHz]

f_o = $\frac{13}{\sqrt{\varepsilon'_r}}$ [GHz]

t = Thickness of MUT (material under test) [mm]

ε'_{rm} = Measured value of ε'_r

ΔT = Difference of measurement temperature from calibration temperature

ΔT_{max} = Maximum temperature change (°C) at test port from calibration temperature after the calibration is performed.

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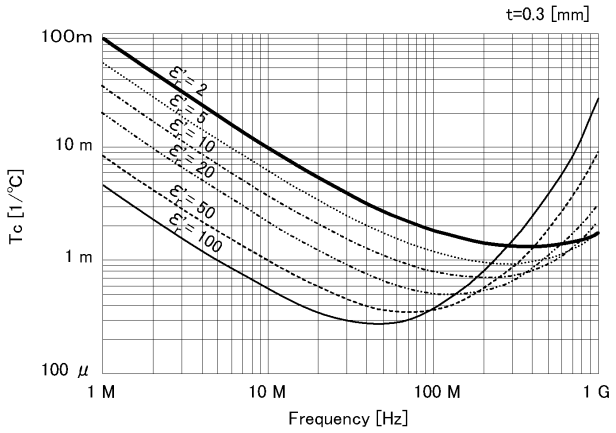

Figure 54. Typical frequency characteristics of temperature coefficient of ε'_r (Thickness = 0.3 mm)

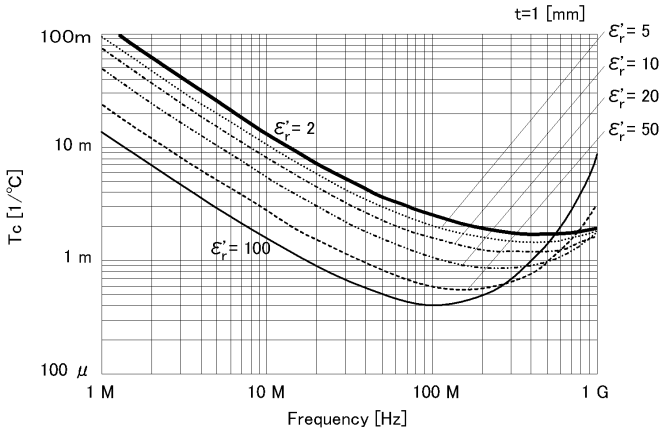

Figure 55. Typical frequency characteristics of temperature coefficient of ε'_r (Thickness = 1 mm)

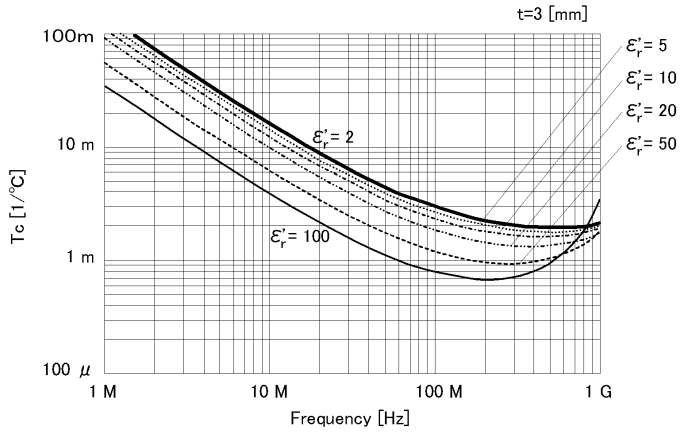

Figure 56. Typical frequency characteristics of temperature coefficient of ε'_r (Thickness = 3 mm)

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Typical Effects of Temperature Change on Permeability Measurement Accuracy

When the temperature at the test port (7-mm connector) of the high temperature cable changes more than 5 °C from the calibration temperature, the typical permeability measurement accuracy involving temperature dependence effects (errors) is applied. The typical permeability accuracy is represented by the sum of error due to temperature coefficient (T_c), hysteresis error ($T_c \times \Delta T_{max}$) and the accuracy at 23 °C ±5 °C.

Typical accuracy of permeability parameters:

μ_r' accuracy = $\left(\frac{\Delta\mu'_{rm}}{\mu'_{rm}}\right)$:

$\pm (E_\mu + E_h + E_i)$ [%]

Loss tangent accuracy of μ_r (= $\Delta\tan\delta$) :

$\pm \frac{(E_\mu + E_h + E_i)}{100}$

where,

E_μ = Permeability measurement accuracy at 23 °C ± 5 °C

$E_h = T_c \times \Delta T$

$E_i = T_c \times \Delta T_{max} \times 0.3$

$T_c = K_4 + K_5 + K_6$

See Figure 57 through Figure 59 for the calculated value of T_c

without temperature compensation

$K_4 = 1 \times 10^{-6} \times (60 + 150 \times f)$

K_5 =

$$1 \times 10^{-2} \times (1 + 10 \times f) \times \frac{|1 - 0.01 \times \{F \times (\mu'_{rm} - 1) + 10\} \times f^2|}{\{F \times (\mu'_{rm} - 1) + 20\} \times f}$$

K_6 =

$$2 \times 10^{-6} \times (0.3 + 3 \times f) \times \frac{\{F \times (\mu'_{rm} - 1) + 20\} \times f}{|1 - 0.01 \times \{F \times (\mu'_{rm} - 1) + 10\} \times f^2|}$$

with temperature compensation

$K_4 = 1 \times 10^{-6} \times (60 + 150 \times f)$

K_5 =

1 MHz ≤ f < 500 MHz

$$1 \times 10^{-2} \times (1 + 10 \times f) \times \frac{|1 - 0.01 \times \{F \times (\mu'_{rm} - 1) + 10\} \times f^2|}{\{F \times (\mu'_{rm} - 1) + 20\} \times f}$$

500 MHz ≤ f ≤ 1 GHz

$$1 \times 10^{-2} \times (5 + 2 \times f) \times \frac{|1 - 0.01 \times \{F \times (\mu'_{rm} - 1) + 10\} \times f^2|}{\{F \times (\mu'_{rm} - 1) + 20\} \times f}$$

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Typical accuracy of permeability parameters (continued):

K_6 = 1 MHz ≤ f < 500 MHz

$$2 \times 10^{-6} \times (0.3 + 3 \times f) \times \frac{\{F \times (\mu'_{rm} - 1) + 20\} \times f}{|1 - 0.01 \times \{F \times (\mu'_{rm} - 1) + 10\} \times f^2|}$$

500 MHz ≤ f ≤ 1 GHz

$$2 \times 10^{-6} \times (1.5 + 0.6 \times f) \times \frac{\{F \times (\mu'_{rm} - 1) + 20\} \times f}{|1 - 0.01 \times \{F \times (\mu'_{rm} - 1) + 10\} \times f^2|}$$

f = Measurement frequency [GHz]

F = $h \ln \frac{c}{b}$ [mm]

h = Height of MUT (material under test) [mm]

b = Inner diameter of MUT [mm]

c = Outer diameter of MUT [mm]

μ' = Measured value of μ'_r

ΔT = Difference of measurement temperature from calibration temperature

ΔT_{max} = Maximum temperature change (°C) at test port from calibration temperature after the calibration is performed.

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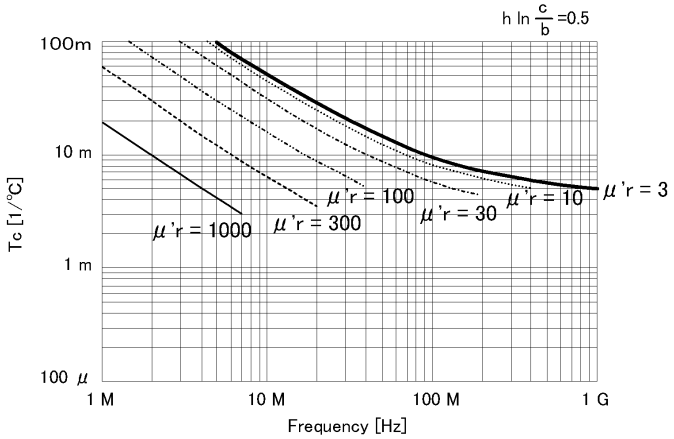

Figure 57. Typical frequency characteristics of temperature coefficient of μ'_r (at $F = 0.5$)

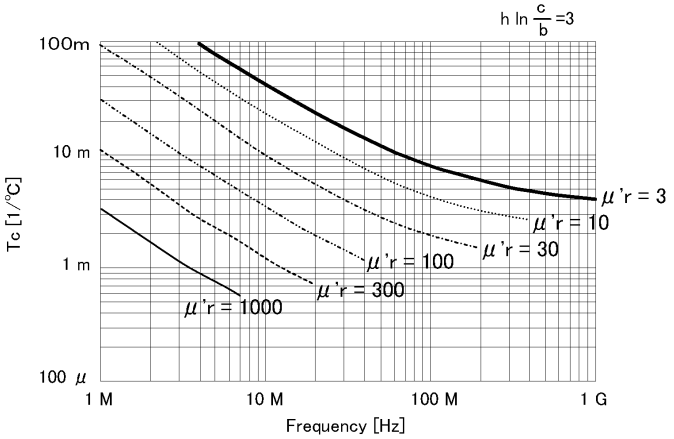

Figure 58. Typical frequency characteristics of temperature coefficient of μ'_r (at $F = 3$)

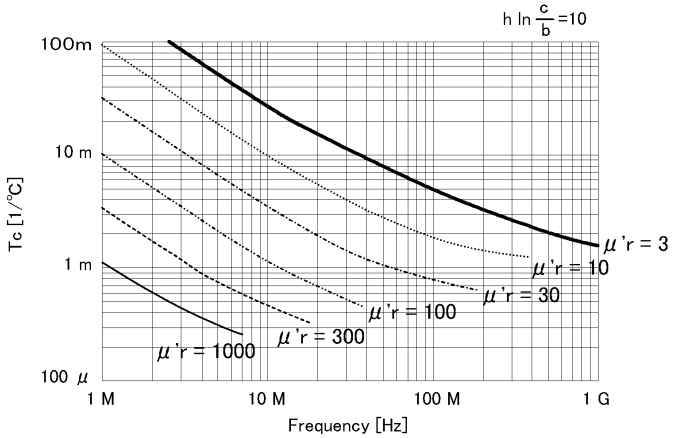

Figure 59. Typical frequency characteristics of temperature coefficient of μ'_r (at F = 10)

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